

GENERAL DESCRIPTION

This document describes the specifications for the IDTF1102 Zero-Distortion™ RF to IF Downconverting Mixer. This device is part of a series of downconverting mixers covering all UTRA bands. See the Part# Matrix for the details of all devices in the series.

The F1102 dual channel device operates with a single 5V supply. It is optimized for operation in a Multi-carrier BaseStation Receiver for RF bands from 698 to 915 MHz with High or Low Side Injection. IF frequencies from 50 to 300 MHz are supported. The F1102 also supports the 400 MHz RF bands with some simple external matching modifications (see page 25). Nominally, the device offers +43 dBm Output IP3 with 330 mA of I_{CC} . Alternately one can adjust 4 resistor values and a toggle pin to run the devices in low current mode (LC mode) with +36 dBm Output IP3 and 235 mA of I_{CC} .

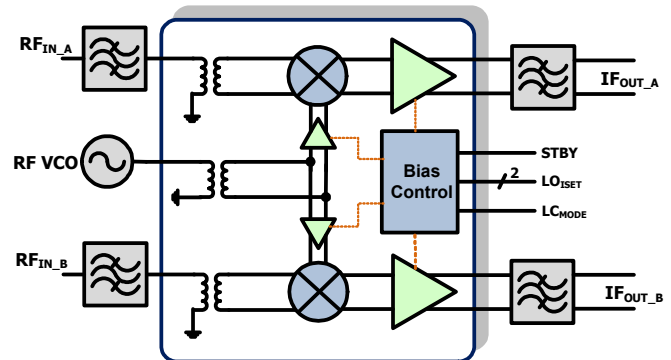
COMPETITIVE ADVANTAGE

In typical basestation receivers the mixer limits the linearity performance for the entire receive system. The F1102 with Zero-Distortion technology dramatically improves the maximum IM₃ interference that the BTS can withstand at a desired Signal to Noise Ratio (SNR.) Alternately, one can run the device in LC Mode to reduce Power consumption significantly.

- ✓ IP_{3O}: ↑ **7 dB** STD Mode, ↑ **3 dB** LC Mode
- ✓ Dissipation: ↓ **40%** LC Mode, ↓ **12%** STD Mode
- ✓ Allows for higher RF gain improving **Sensitivity**

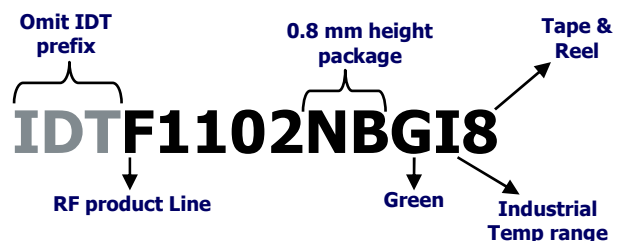

FEATURES

- Dual Path for Diversity Systems
- Ideal for Multi-Carrier Systems
- 9.0 dB Gain
- Ultra linear:
 - **+43 dBm IP_{3O} (STD Mode)**
 - +36 dBm IP_{3O} (LC Mode)
- Low NF < 10 dB
- Extended LO level range for MIMO (-6 dBm)
- 200 Ω output impedance
- Ultra high +13 dBm P1dB_I
- **Pin Compatible** with existing solutions
- 6x6 36 pin package
- **Power Down mode**
- < 200 nsec settling from Power Down
- Minimizes Synth pulling in Standby Mode
- Low Current Mode : **I_{CC} = 235 mA**
- Standard Mode: I_{CC} = 330 mA

DEVICE BLOCK DIAGRAM

PART# MATRIX

Part#	RF freq range	UTRA bands	IF freq range	Typ. Gain	Injection
F1100	698 - 915	5,6,8,12,13,14,17,19,20	150 - 450	8.3	High Side
F1102	400 - 1000	5,6,8,12,13,14,17,19,20	50 - 300	9.0	Both
F1150 ²	1700 - 2200	1,2,3,4,9,10, 33, 34,35, 36, 37,39	50 - 450	8.5	High Side
F1152	1400 - 2200	1,2,3,4,9,10, 21 ¹ , 24 ¹ , 33, 34,35, 36, 37,39	50 - 350	8.5	Low Side
F1162	2300 – 2700	7,38,40,41 ²	50 – 500	8.8	Low Side

1 - with High side injection
2 - With High side or Low side injection

ORDERING INFORMATION


ABSOLUTE MAXIMUM RATINGS

VCC to GND	-0.3V to +5.5V
STBY, LC _{MODE}	-0.3V to (VCC ₋ + 0.3V)
IF_A+, IF_B+, IF_A-, IF_B-, LO1_ADJ, LO2_ADJ	-0.3V to (VCC ₋ + 0.3V)
LO_IN, LO_IN_ALT, RF_A, RF_B	-0.3V to +0.3V
IF_BiasA, IF_BiasB to GND	-0.3V to +0.3V
RF Input Power (RF_A, RF_B)	+20dBm
Continuous Power Dissipation	2.2W
θ_{JA} (Junction – Ambient)	+35°C/W
θ_{JC} (Junction – Case) The Case is defined as the exposed paddle	+2.5°C/W
Operating Temperature Range (Case Temperature)	T _C = -40°C to +100°C
Maximum Junction Temperature	150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s) .	+260°C

Stresses above those listed above may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

IDTF1102 SPECIFICATION (400 – 1000 MHz MIXER w/HIGH OR LOW SIDE INJECTION)

Specifications apply at $V_{CC} = +5.0V$, $F_{RF} = 850 \text{ MHz}$, $F_{IF} = 200 \text{ MHz}$, Hi-Side, $P_{LO} = 0 \text{ dBm}$, $T_C = +25^\circ\text{C}$, $STBY = GND$, $LC_{MODE} = V_{IH}$ (STD Mode), EVKit BOM = Standard Mode, Transformer Loss included (not de-embedded) unless otherwise noted.

Parameter	Comment	Symbol	min	typ	max	units
Logic Input High	For Standby, LC_{MODE} Pins	V_{IH}	2			V
Logic Input Low	For Standby, LC_{MODE} Pins	V_{IL}			0.8	V
Logic Current	For Standby Pin	I_{IH}, I_{IL}	-30		+30	μA
Logic Current	LC_{MODE} Pin	I_{IH}, I_{IL}	-100		-20	μA
Supply Voltage(s)	All V_{CC} pins	V_{CC}		4.75 to 5.25		V
Operating Temperature	Case Temperature	T_{CASE}		-40 to +100		degC
Supply Current	Total V_{CC} , STD Mode ▪ Total Both Channels	I_{STD}		330	370¹	mA
Supply Current	Total V_{CC} , LC Mode ▪ $LC_{MODE} = GND$ ▪ EVkit BOM = LC Mode ▪ Total Both Channels	I_{LC}		235	260	mA
Supply Current	Standby Mode ▪ $STBY = V_{IH}$ ▪ Total Both Channels ▪ STD Mode	I_{STBY}		22	30	mA
RF Freq Range	Operating Range	F_{RF}		400 ³ – 1000		MHz
IF Freq Range	Operating Range	F_{IF}		50 to 300		MHz
LO Freq Range	Operating LO Range	F_{LO}		500 to 1150		MHz
LO Power	Operating LO Range	P_{LO}		-6 to +6		dBm
RF Input Impedance	Single Ended Return Loss ~17 dB	Z_{RF}		50		Ω
IF Output Impedance	Differential Return Loss ~ 13 dB	Z_{IF}		200		Ω
LO port Impedance	Single Ended Return Loss ~15 dB	Z_{LO}		50		Ω
Settling Time	• Pin = -13 dBm • Gate STBY from V_{IH} to V_{IL} • Time for IF Signal to settle to within 0.1 dB of final value	T_{SETT}		0.175		μsec
Gain STD Mode	Conversion Gain • $F_{RF} = 698 \text{ MHz}$ • $LC_{MODE} = V_{IH}$ • EVkit BOM = STD Mode • $F_{IF} = 150 \text{ MHz}$ (Low Side Inj.)	G_{STD}	8.5	9.2	9.9	dB
Gain LC Mode	Conversion Gain • $F_{RF} = 915 \text{ MHz}$ • $LC_{MODE} = GND$ • EVkit BOM = LC Mode • $F_{IF} = 200 \text{ MHz}$ (High Side Inj.)	G_{LC}	7.8	8.5	9.2	dB

IDTF1102 SPECIFICATION (CONTINUED)

Parameter	Comment	Symbol	min	typ	max	units
NF STD Mode	<ul style="list-style-type: none"> • $LC_{MODE} = V_{IH}$ • EVkit BOM = STD Mode • $F_{IF} = 200$ MHz (High Side Inj.) 	NF_{STD}		9.5		dB
NF LC Mode	<ul style="list-style-type: none"> • $LC_{MODE} = GND$ • EVkit BOM = LC Mode • $F_{IF} = 200$ MHz (High Side Inj.) 	NF_{LC}		9.3		dB
NF w/Blocker	<ul style="list-style-type: none"> ▪ -100 MHz offset blocker ▪ $P_{IN} = +10$ dBm ▪ $F_{IF} = 200$ MHz 	NF_{BLK}		21.7		dB
Output IP3 – Narrowband	<ul style="list-style-type: none"> ▪ $P_{IN} = -10$ dBm per tone ▪ 800 KHz Tone Separation ▪ $F_{IF} = 200$ MHz (High Side Inj.) ▪ $F_{RF} = 850$ MHz 	$IP3_{O1}$	39 ²	43		dBm
Output IP3 – Wideband	<ul style="list-style-type: none"> ▪ $P_{IN} = -10$ dBm per tone ▪ 15 MHz Tone Separation ▪ $F_{IF} = 200$ MHz (High Side Inj.) 	$IP3_{O2}$		42		dBm
Output IP3 – LC_{MODE}	<ul style="list-style-type: none"> ▪ $P_{IN} = -10$ dBm per tone ▪ $F_{IF} = 200$ MHz (High Side Inj.) ▪ 800 KHz Tone Separation ▪ $LC_{MODE} = GND$ ▪ $F_{RF} = 915$ MHz 	$IP3_{O3}$	33	36		dBm
2RF – 2LO rejection	<ul style="list-style-type: none"> ▪ $P_{RF} = -10$ dBm ▪ Frequency = $F_{RF} + \frac{1}{2} F_{IF}$ 	2x2		-78		dBc
1 dB Compression	<ul style="list-style-type: none"> ▪ Input referred 	$P1dB_{I1}$	11.9	12.5		dBm
1 dB Compression - LC_{MODE}	<ul style="list-style-type: none"> ▪ Input referred ▪ $LC_{MODE} = GND$ 	$P1dB_{I2}$	9.0	10.2		dBm
Gain Comp. w/blocker	<ul style="list-style-type: none"> ▪ Blocker → unmodulated tone ▪ $P_{IN} = +8$ dBm, 20 MHz offset ▪ Signal Pin Tone = -20 dBm ▪ Measure ΔG of signal 	ΔG_{AC}		0.15		dB
Spur: 5RF X -4LO	<ul style="list-style-type: none"> ▪ $F_{LO} = 1087.5$ MHz ▪ $F_{IF} = 190$ MHz (High Side Inj.) ▪ Desired $F_{RF} = 897.5$ MHz ▪ Spur Freq = 908 MHz ▪ Pin = +5 dBm ▪ STD Mode 	$SPUR_1$		-97	-89	dBc
Channel Isolation	IF_B Pout vs. IF_A w/ RF_A input	ISO_C	45	51		dB
LO to IF leakage		ISO_{LI}		-22	-15	dBm
RF to IF leakage	Pin = -10 dBm	ISO_{RI}		-26	-20	dBm
LO to RF leakage		ISO_{LR}		-40		dBm

Notes:

- 1 – Items in min/max columns in ***bold italics*** are Guaranteed by Test
- 2 – All other Items in min/max columns are Guaranteed by Design Characterization
- 3 – Normal RF range is 698 – 915 MHz. See Page 25 for modifications for 400 – 500 MHz operation

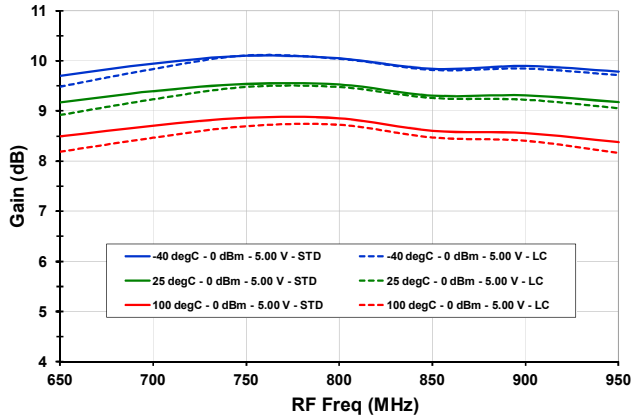
TYPICAL OPERATING CONDITIONS

Unless otherwise Noted, the following Apply to the Typ Ops Graphs

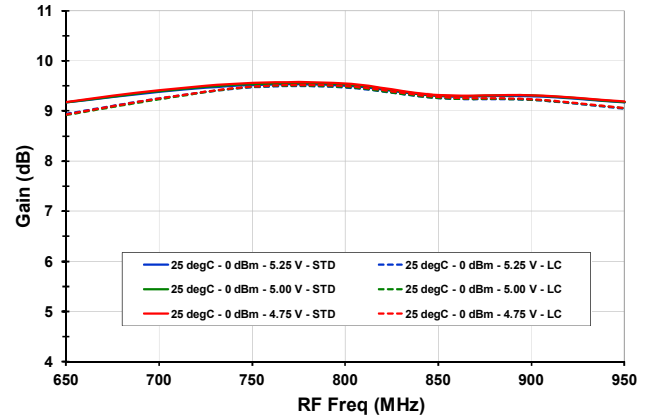
- 800 KHz Tone Spacing
- High Side injection graphs with 200MHz IF (pages 6 – 10)
- Low Side injection graphs with 150MHz IF (pages 11 – 14)
- Average of Channel A & Channel B
- Pin = – 10 dBm per Tone
- LO port = Pin 19 (Main Port)
- Listed Temperatures are Case Temperature (T_C or T_{CASE} = Case Temperature)
- Where noted, T_A or T_{AMB} = Ambient Temperature
- Transformer losses are de-embedded

TYPICAL OPERATING CONDITIONS [IF = 200 MHz, High Side Injection] (-1-)

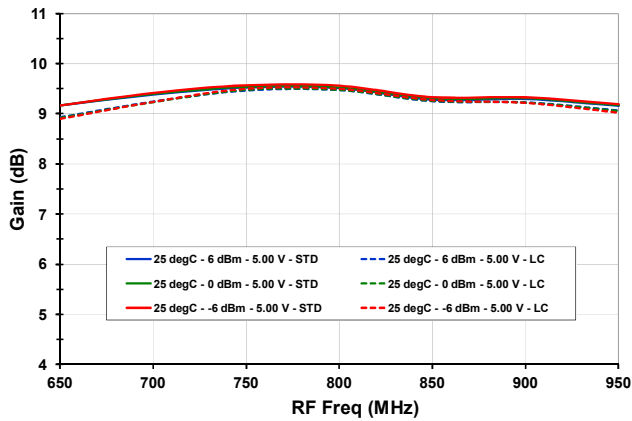
Gain vs. T_{CASE}



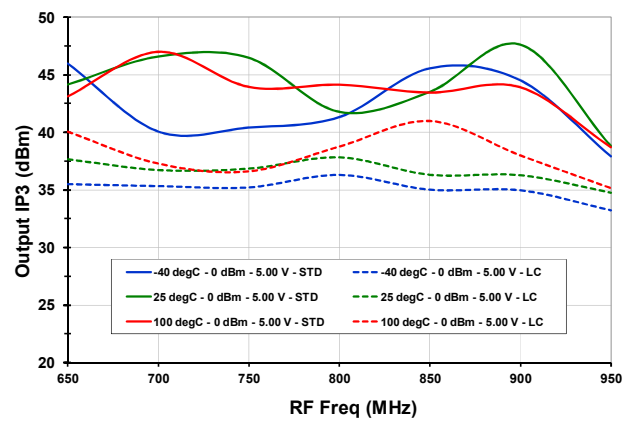
Gain vs. V_{CC}



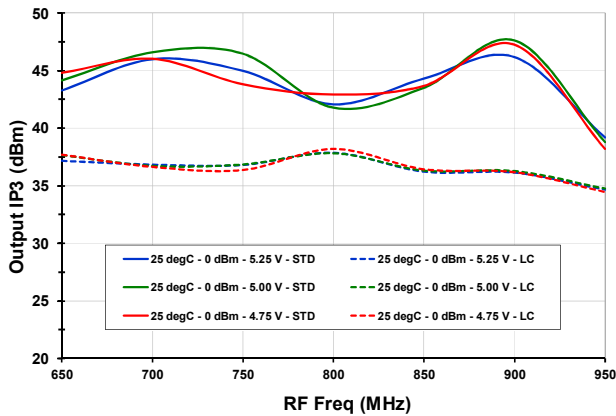
Gain vs. LO Level



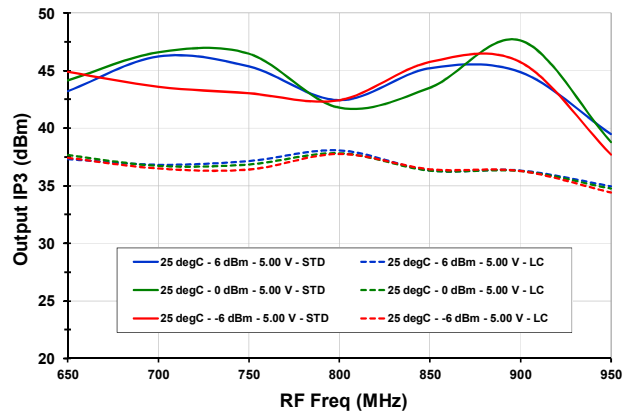
Output IP3 vs. T_{CASE}



Output IP3 vs. V_{CC}

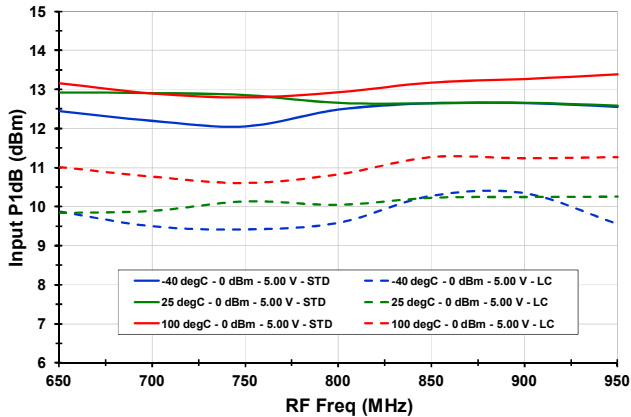


Output IP3 vs. LO Level

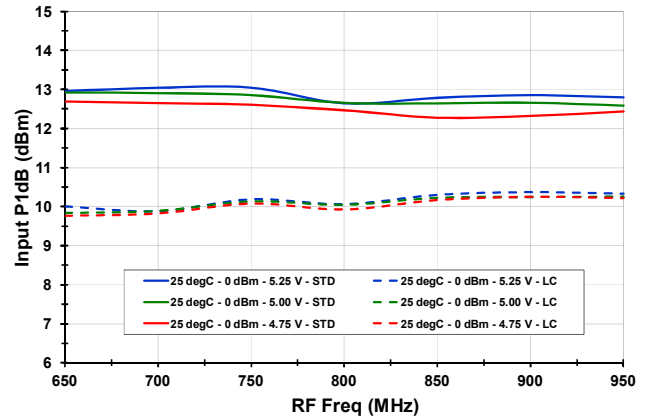


TYPICAL OPERATING CONDITIONS [IF = 200 MHz, High Side Injection] (-2-)

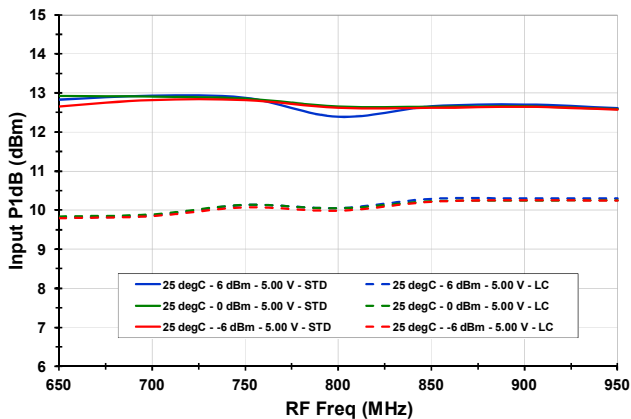
P1dB vs. T_{CASE}



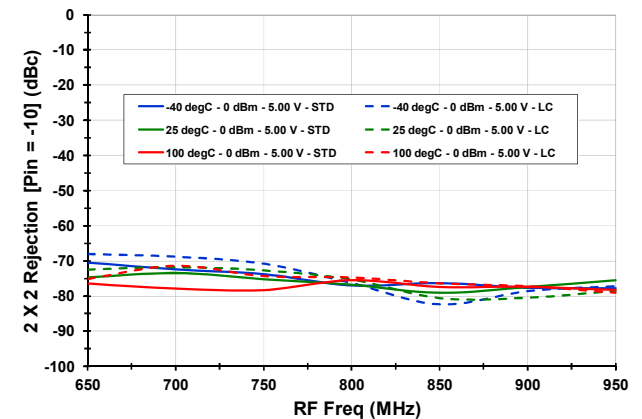
P1dB vs. V_{CC}



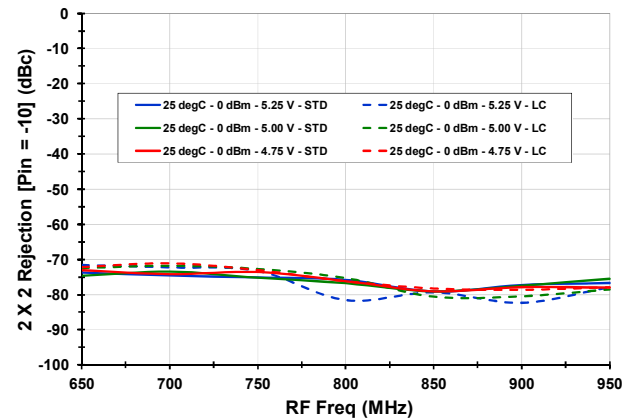
P1dB vs. LO Level



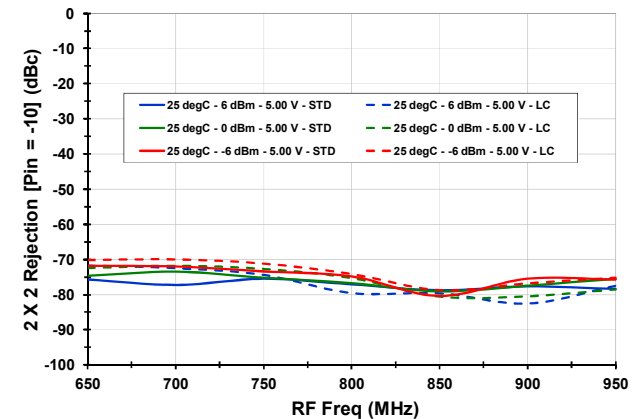
2RF x 2LO rejection vs. T_{CASE}



2RF x 2LO Rejection vs. V_{CC}

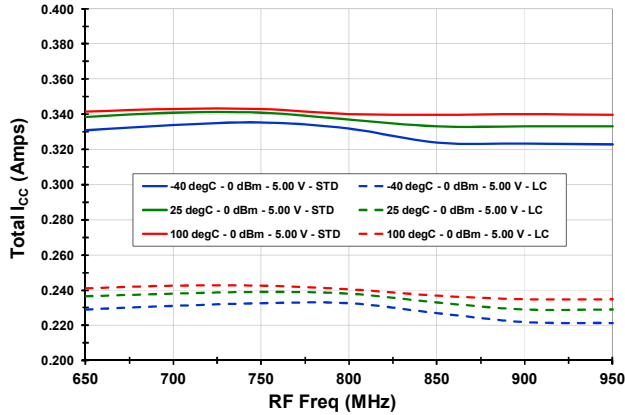


2RF x 2LO Rejection vs. LO Level

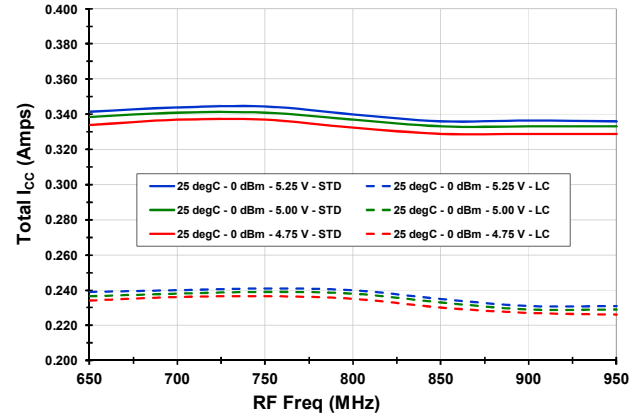


TYPICAL OPERATING CONDITIONS [IF = 200 MHz, High Side Injection] (-3-)

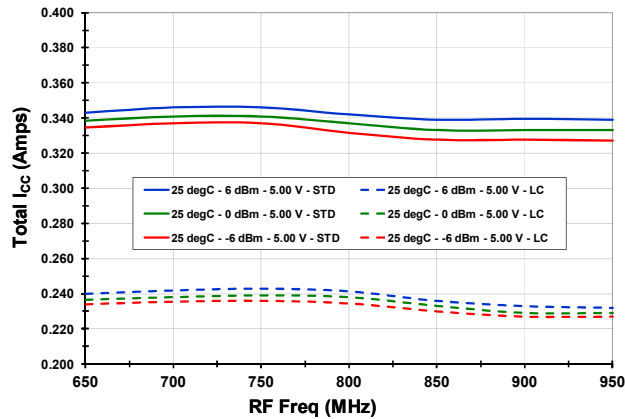
I_{CC} vs. T_{CASE}



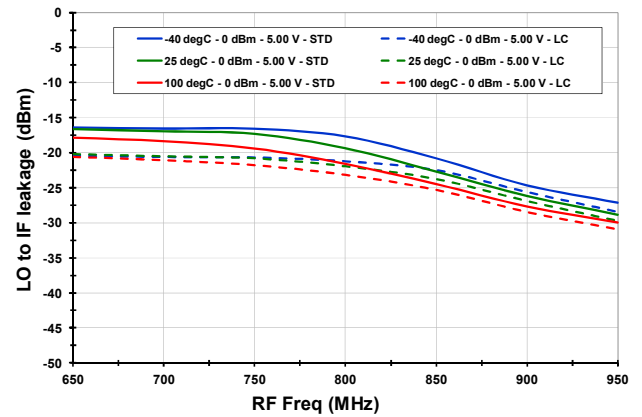
I_{CC} vs. V_{CC}



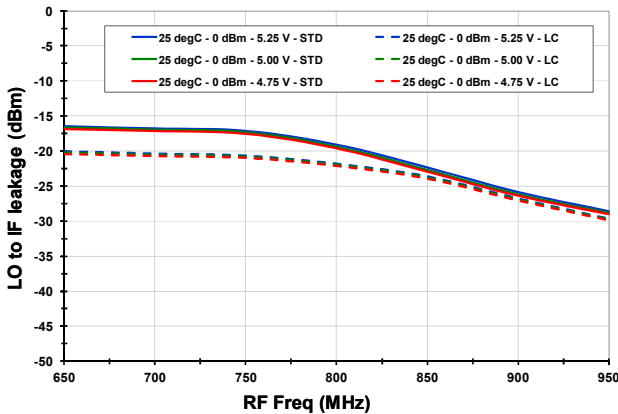
I_{CC} vs. LO Level



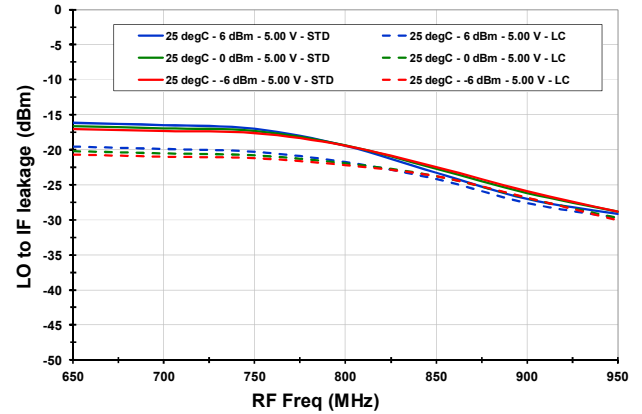
LO-IF Leakage vs. T_{CASE}



LO-IF Leakage vs. V_{CC}

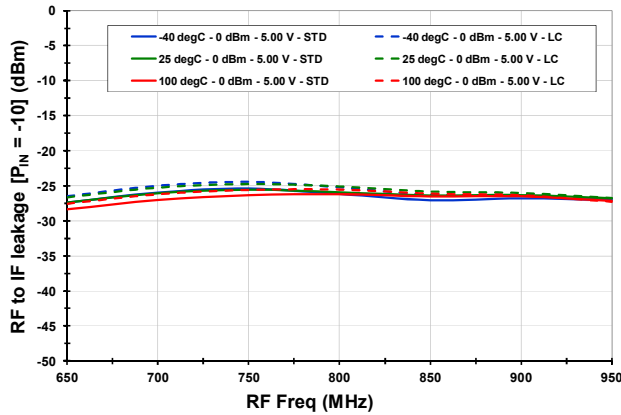


LO-IF Leakage vs. LO Level

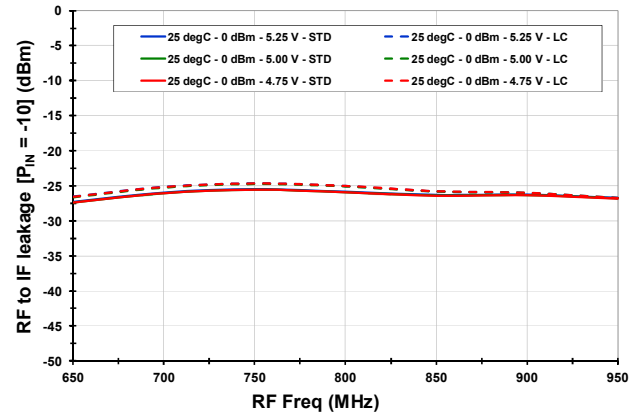


TYPICAL OPERATING CONDITIONS [IF = 200 MHz, High Side Injection] (-4-)

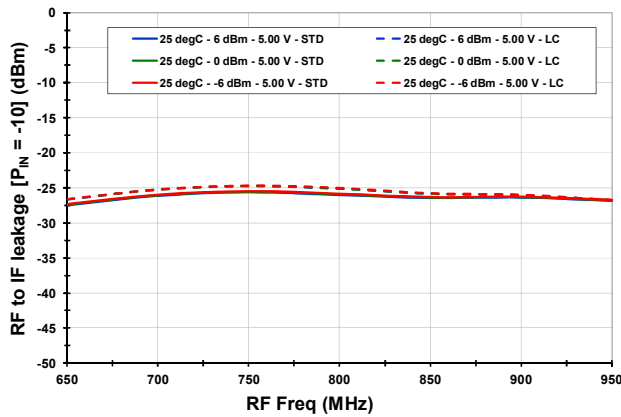
RF-IF Leakage vs. T_{CASE}



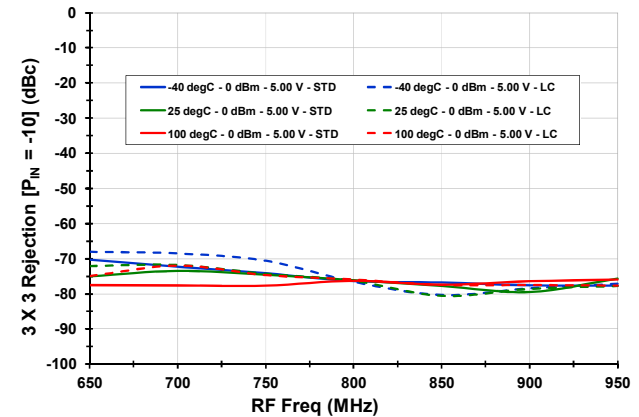
RF-IF Leakage vs. V_{CC}



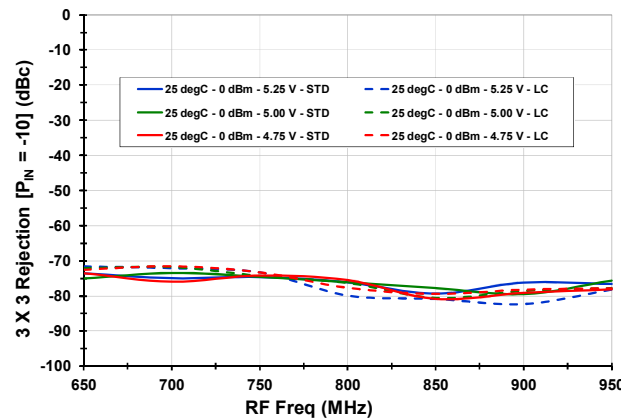
RF-IF Leakage vs. LO Level



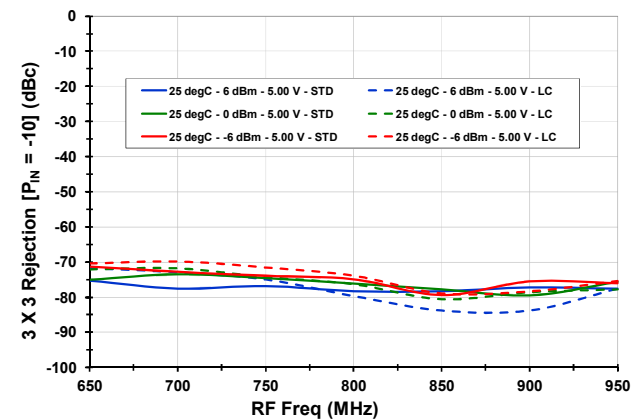
3RF X 3LO Rejection vs. T_{CASE}



3RF X 3LO Rejection vs. V_{CC}

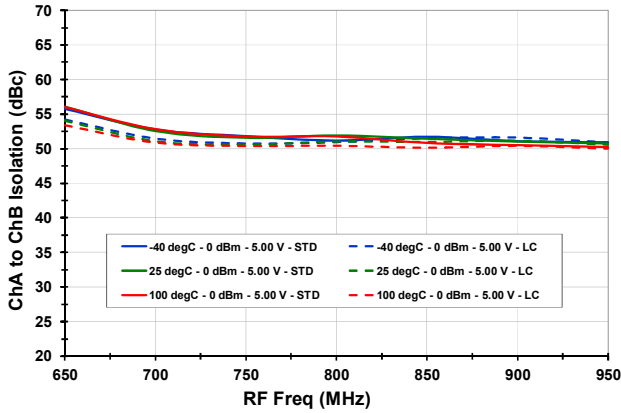


3RF X 3LO Rejection vs. LO Level

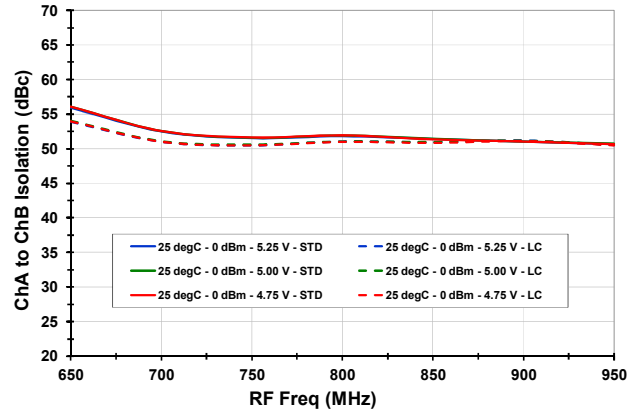


TYPICAL OPERATING CONDITIONS [IF = 200 MHz, High Side Injection] (-5-)

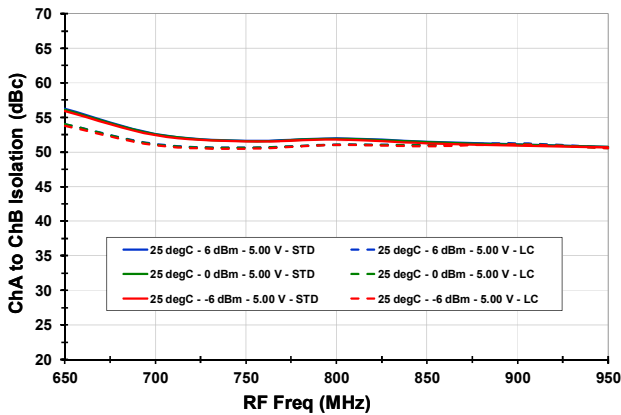
Channel Isolation vs. T_{CASE}



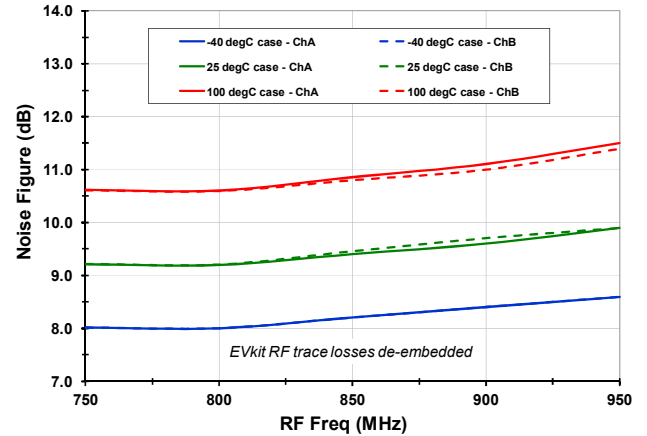
Channel Isolation vs. V_{CC}



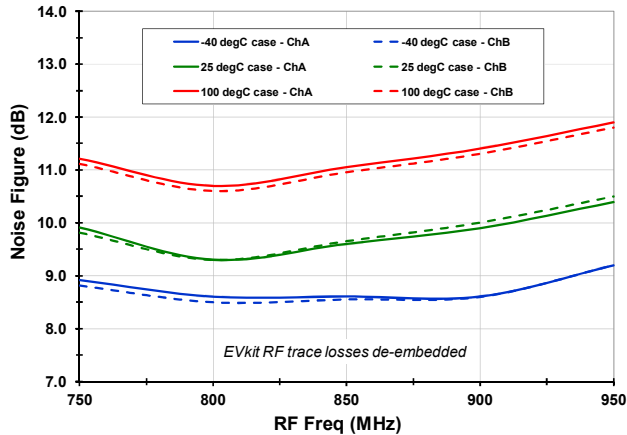
Channel Isolation vs. LO Level



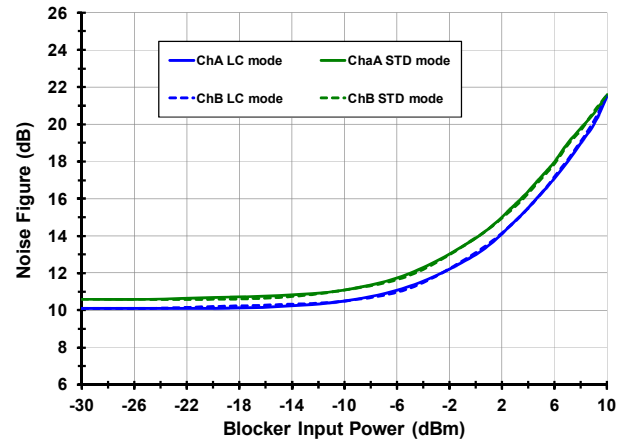
Noise Figure vs. T_{CASE} (LC Mode)



Noise Figure vs. T_{CASE} (STD Mode)

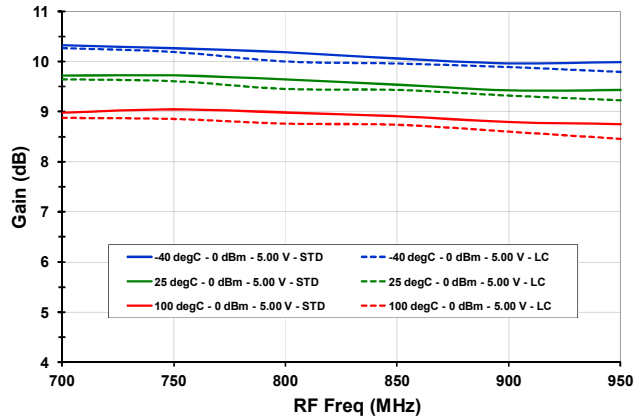


NF vs. Blocker (RF = 850 MHz, IF = 200 MHz, T_A = 25C)

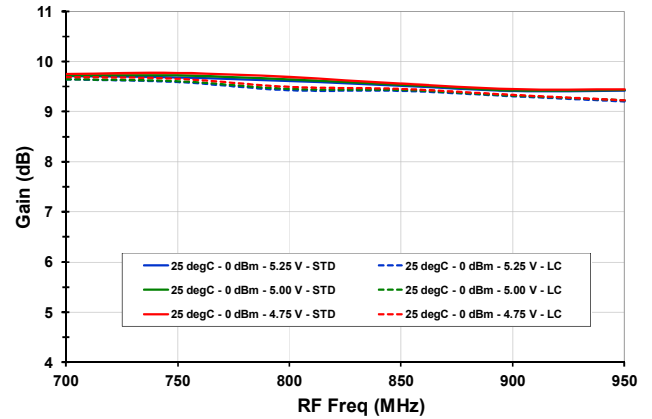


TYPICAL OPERATING CONDITIONS [IF = 150 MHz, Low Side Injection] (-6-)

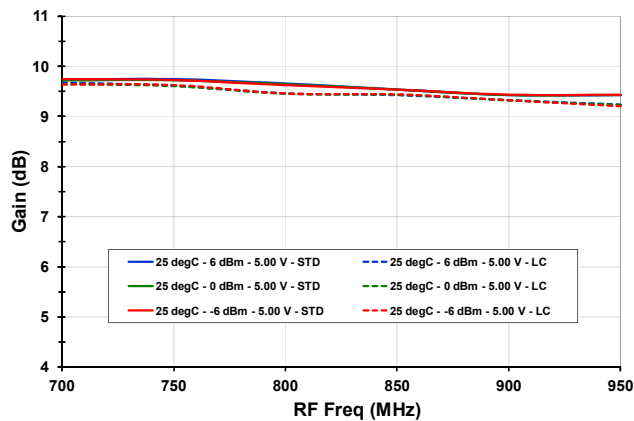
Gain vs. T_{CASE}



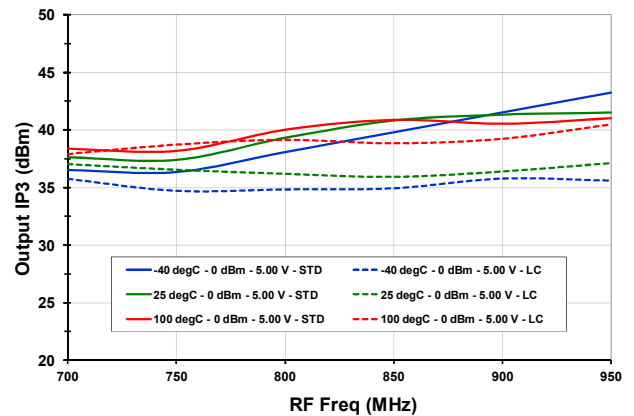
Gain vs. V_{CC}



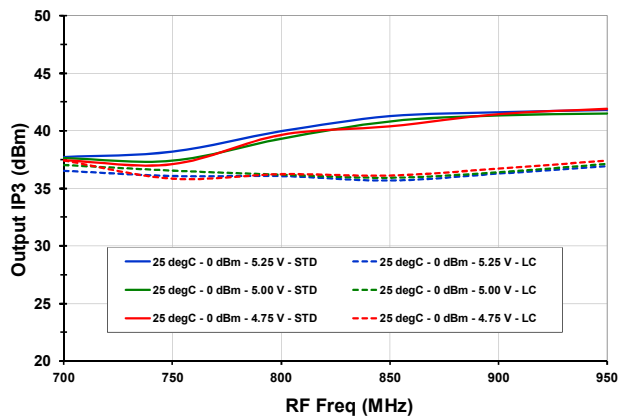
Gain vs. LO level



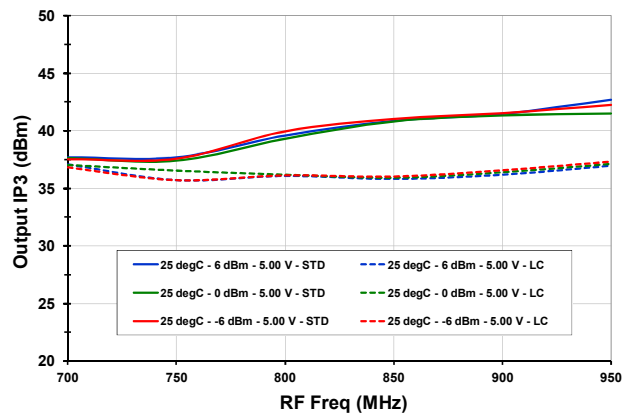
Output IP3 vs. T_{CASE}



Output IP3 vs. V_{CC}

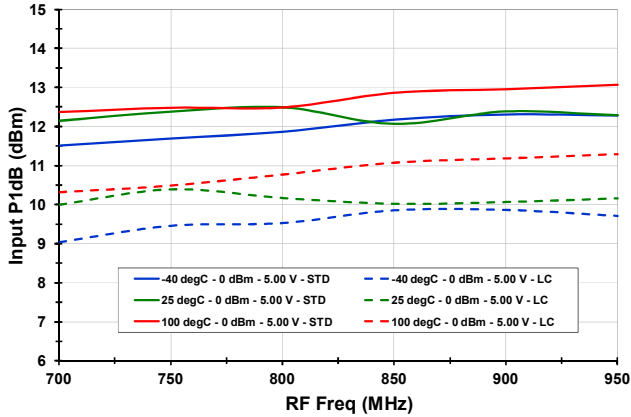


Output IP3 vs. LO Level

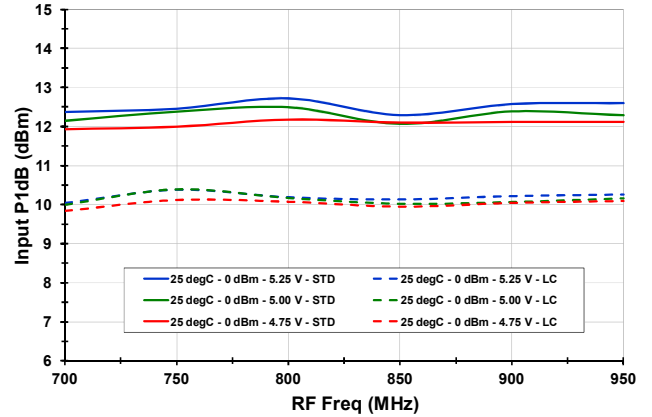


TYPICAL OPERATING CONDITIONS [IF = 150 MHz, Low Side Injection] (-7-)

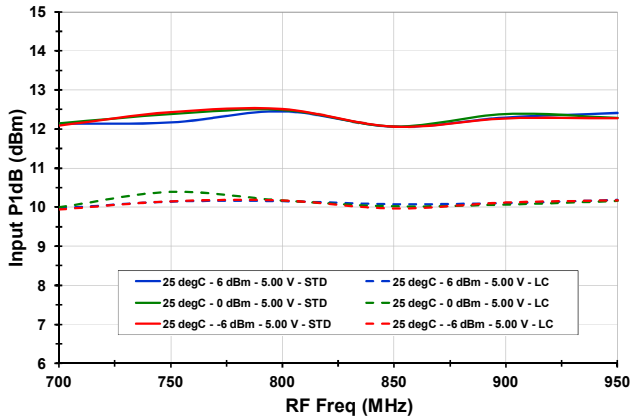
P1dB vs. T_{CASE}



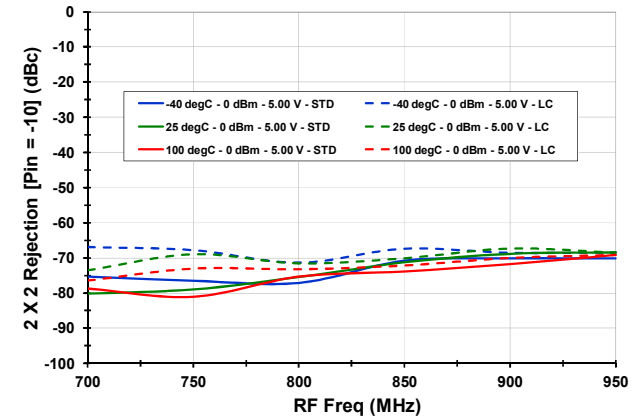
P1dB vs. V_{CC}



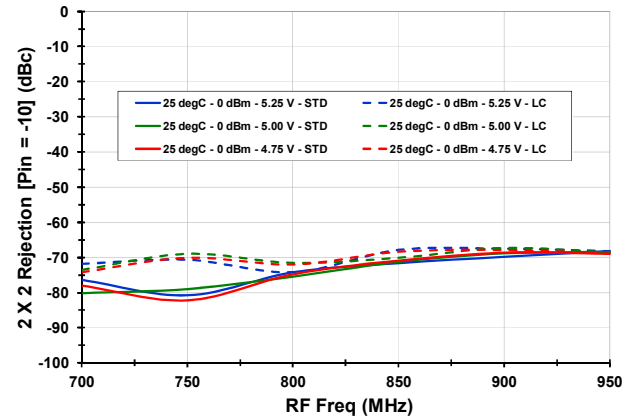
P1dB vs. LO Level



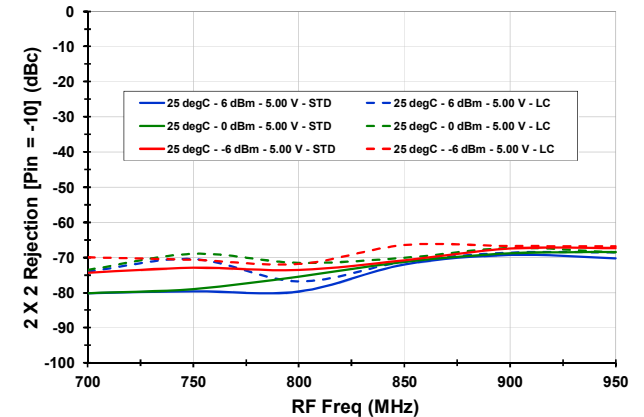
2RF x 2LO rejection vs. T_{CASE}



2RF x 2LO Rejection vs. V_{CC}

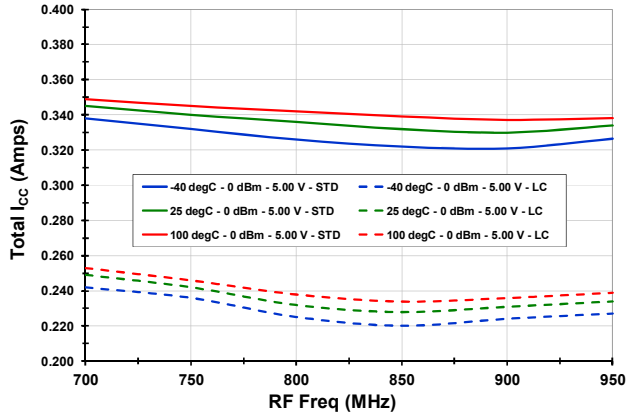


2RF x 2LO rejection vs. LO Level

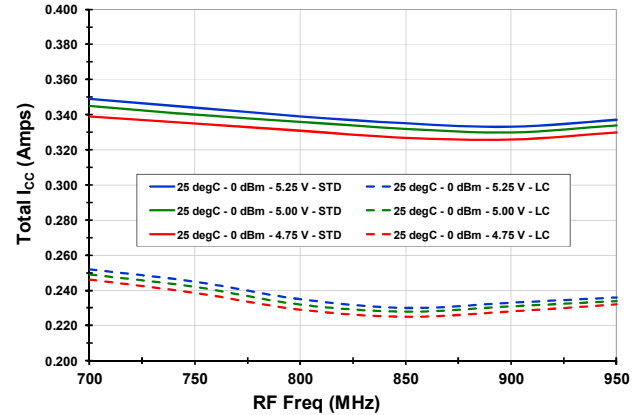


TYPICAL OPERATING CONDITIONS [IF = 150 MHz, Low Side Injection] (-8-)

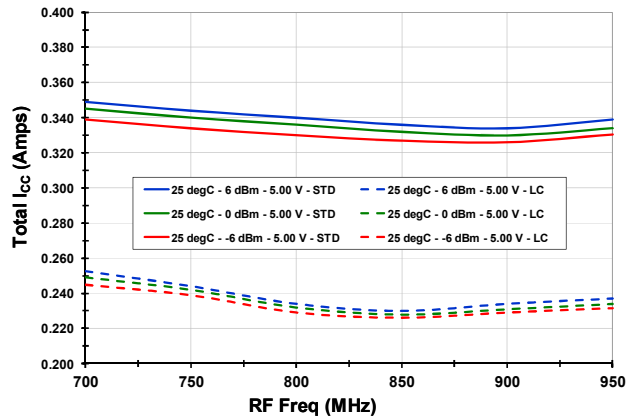
I_{CC} vs. T_{CASE}



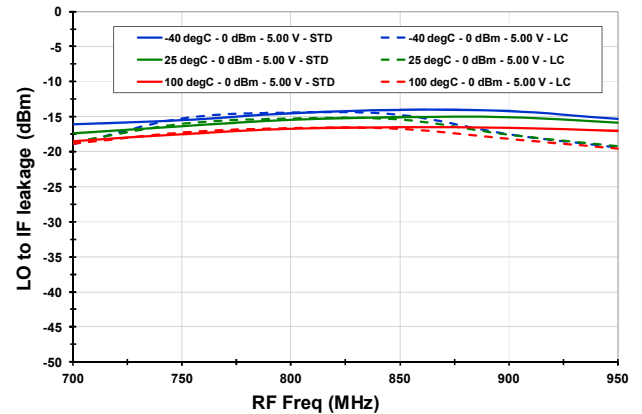
I_{CC} vs. V_{CC}



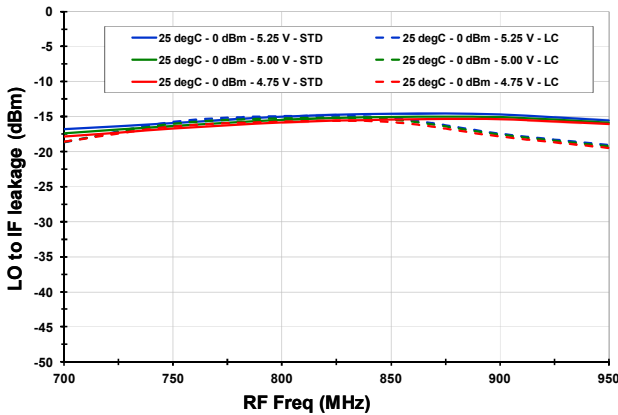
I_{CC} vs. LO Level



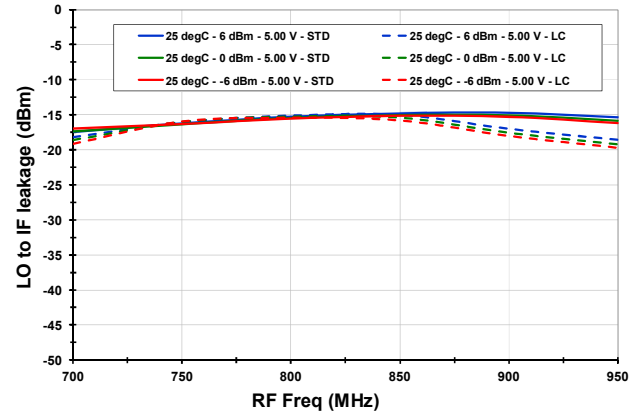
LO-IF Leakage vs. T_{CASE}



LO-IF Leakage vs. V_{CC}

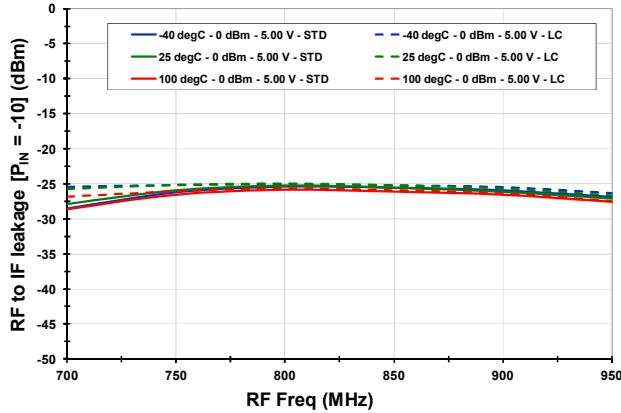


LO-IF Leakage vs. LO Level

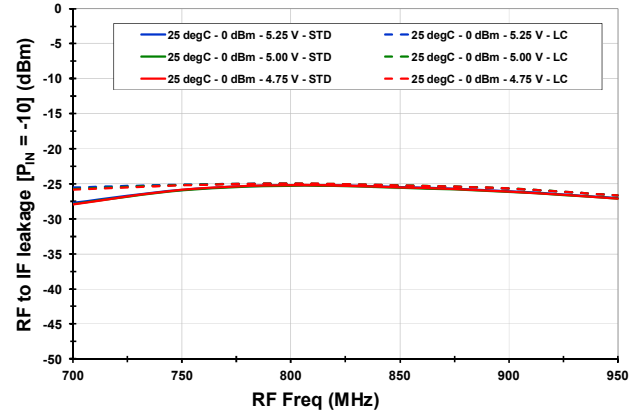


TYPICAL OPERATING CONDITIONS [IF = 150 MHz, Low Side Injection] (-9-)

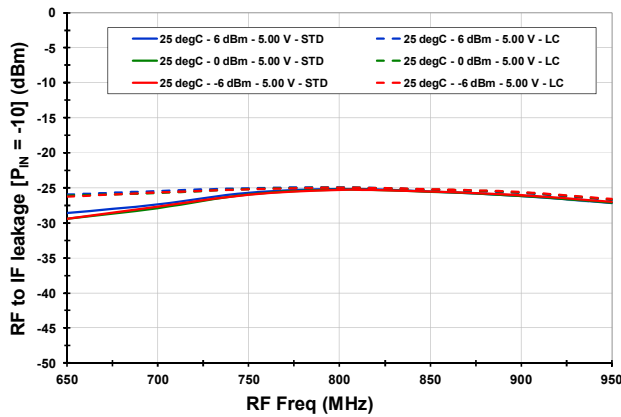
RF-IF Leakage vs. T_{CASE}



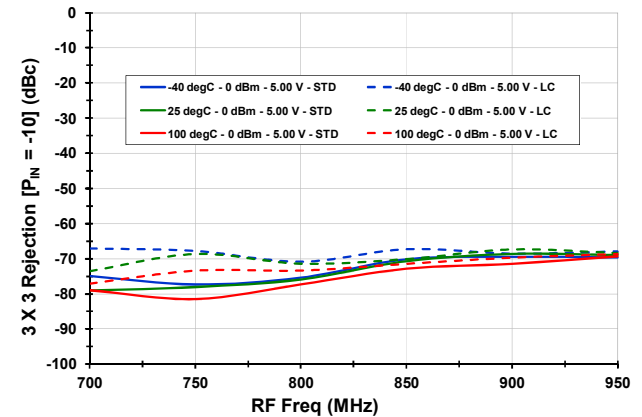
RF-IF Leakage vs. V_{CC}



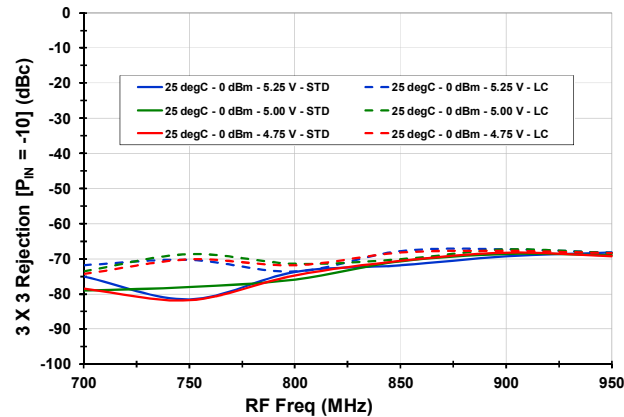
RF-IF Leakage vs. LO Level



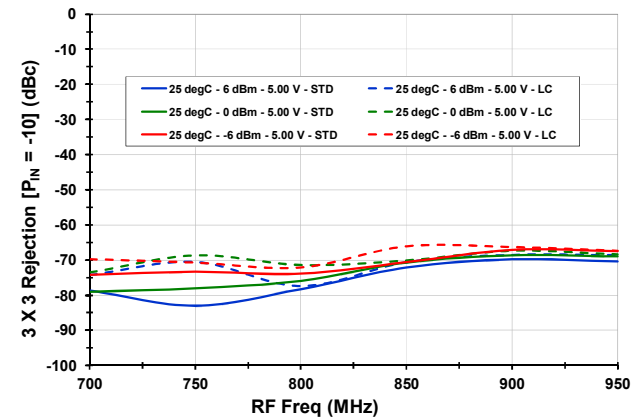
3RF X 3LO Rejection vs. T_{CASE}



3RF X 3LO Rejection vs. V_{CC}

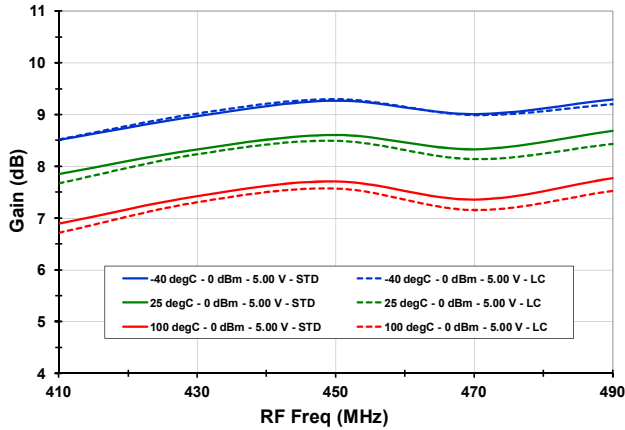


3RF X 3LO Rejection vs. LO Level

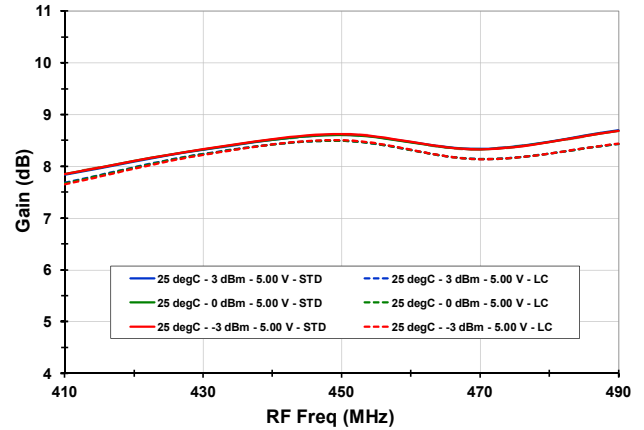


TYPICAL OPERATING CONDITIONS [400 MHz Bands see modifications on p. 25] (-10-)

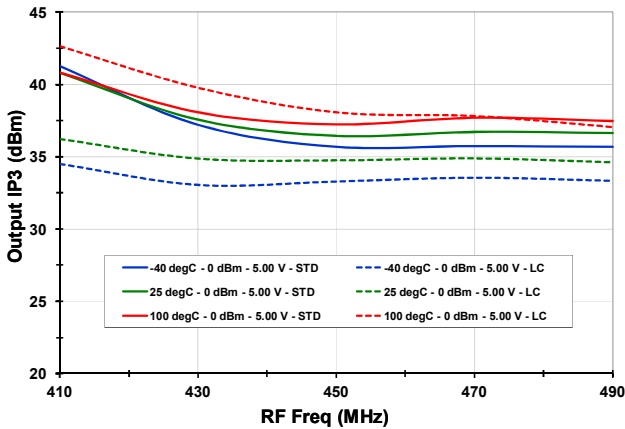
Gain vs. T_{CASE} (130 MHz IF)



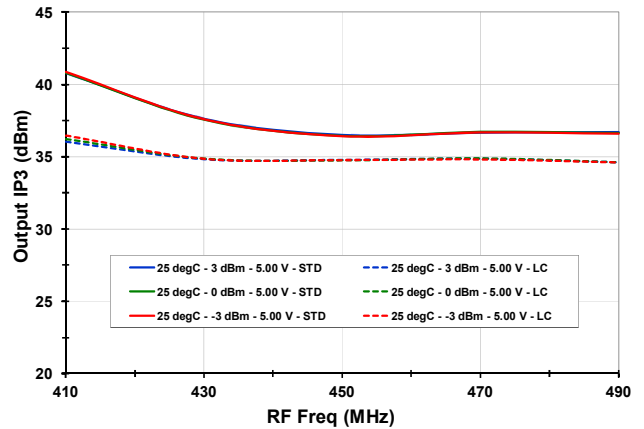
Gain vs. LO Level (130 MHz IF)



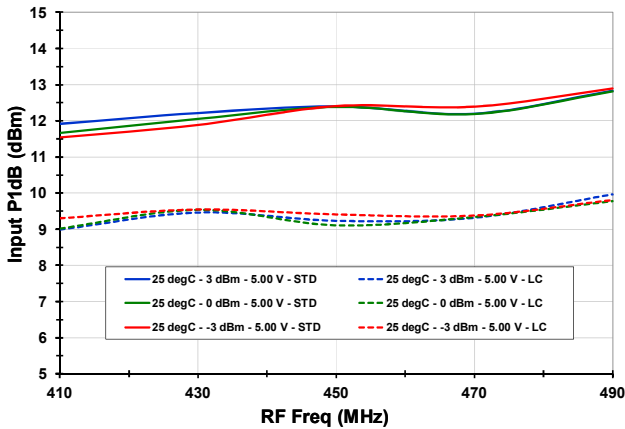
Output IP3 vs. T_{CASE} (130 MHz IF)



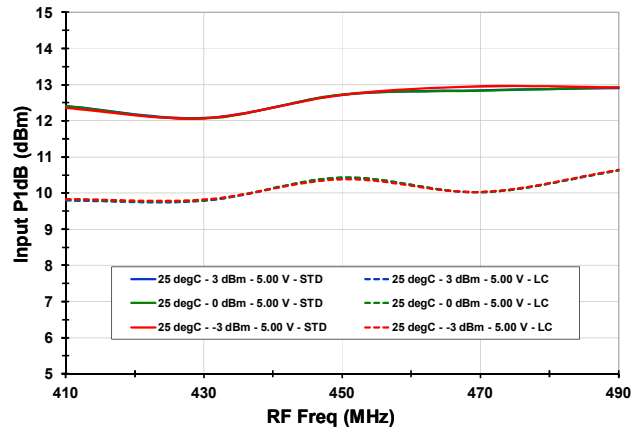
Output IP3 vs. LO Level (130 MHz IF)



P1dB vs. LO Level (70 MHz IF)



P1dB vs. LO Level (130 MHz IF)

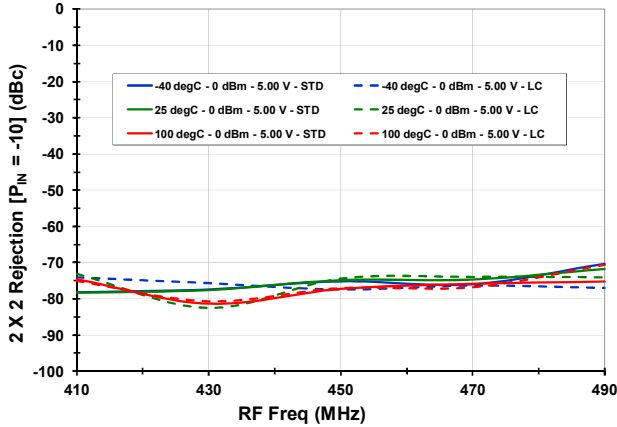


RF to IF Dual Downconverting Mixer

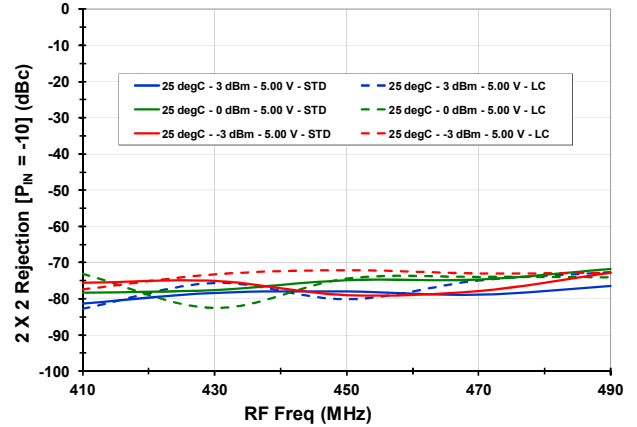
400 – 1000 MHz F1102NBGI

TYPICAL OPERATING CONDITIONS [400 MHz Bands see modifications on p. 25] (-11-)

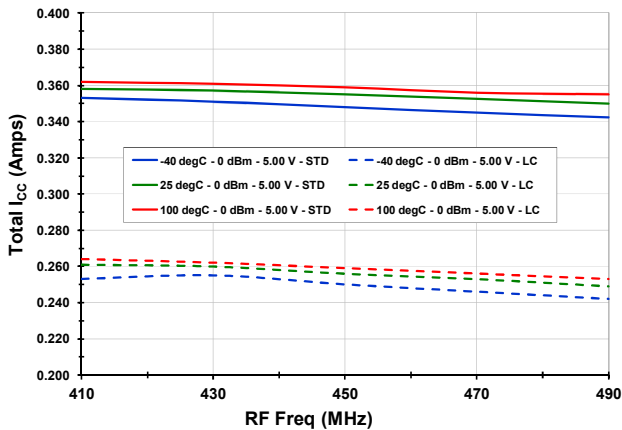
2RF x 2LO vs. T_{CASE} (130 MHz IF)



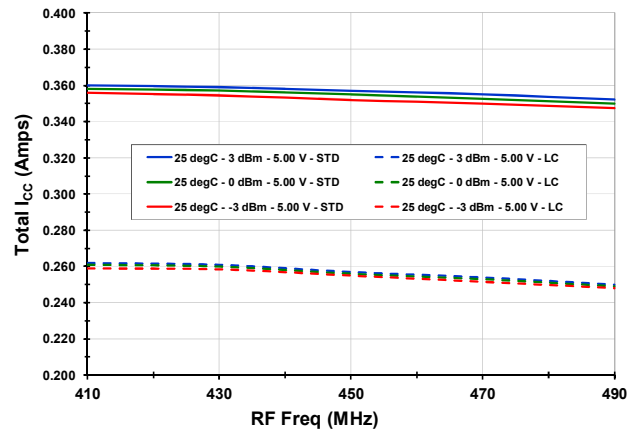
2RF x 2LO vs. LO Level (130 MHz IF)



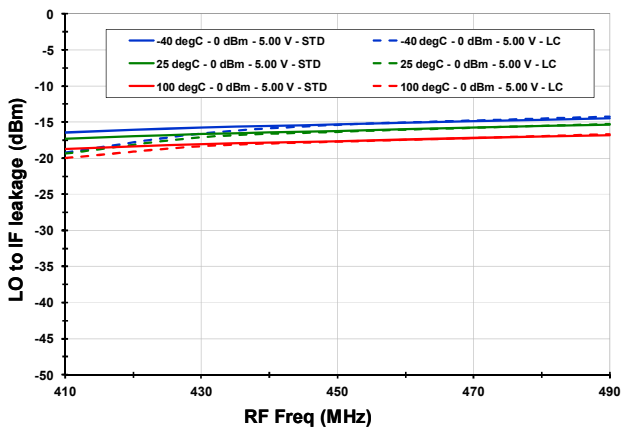
I_{CC} vs. T_{CASE} (130 MHz IF)



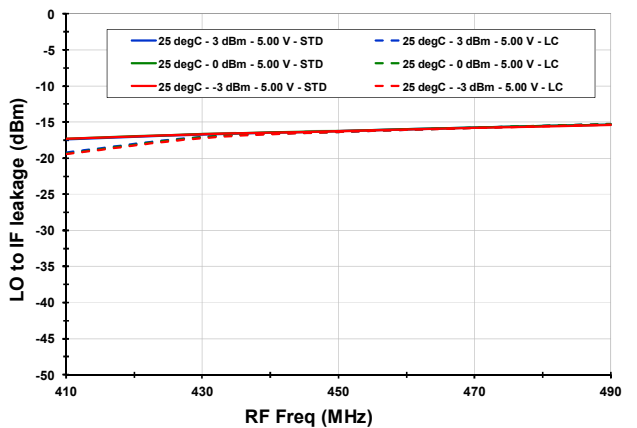
I_{CC} vs. LO Level (130 MHz IF)



LO to IF Leakage vs. T_{CASE} (130 MHz IF)

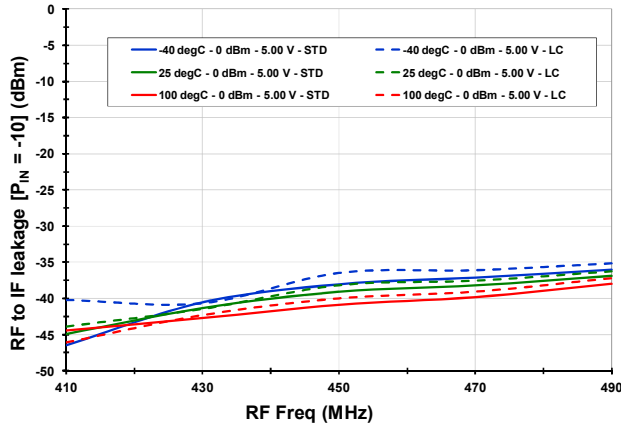


LO to IF Leakage vs. LO Level (130 MHz IF)

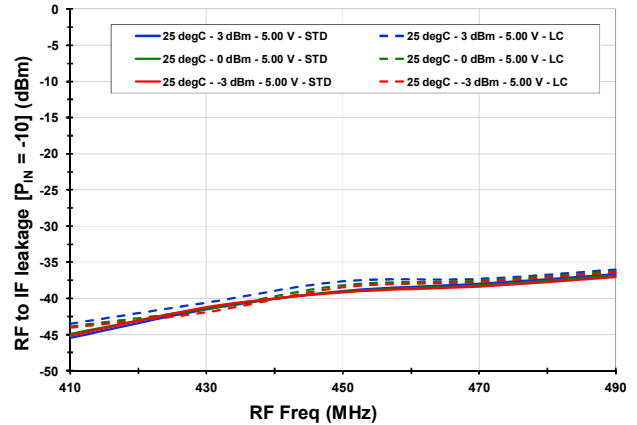


TYPICAL OPERATING CONDITIONS [400 MHz Bands see modifications on p. 25] (-12-)

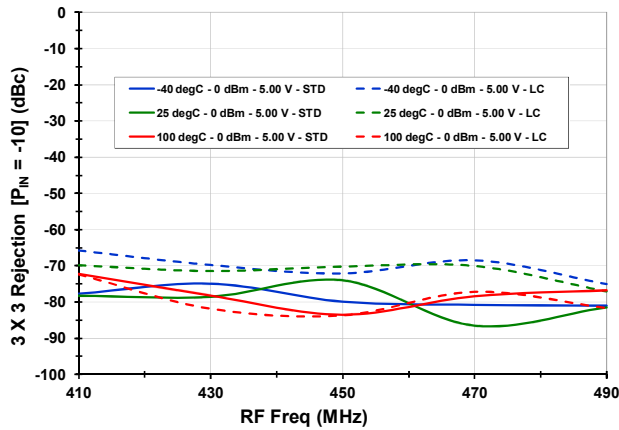
RF to IF Leakage vs. T_{CASE} (130 MHz IF)



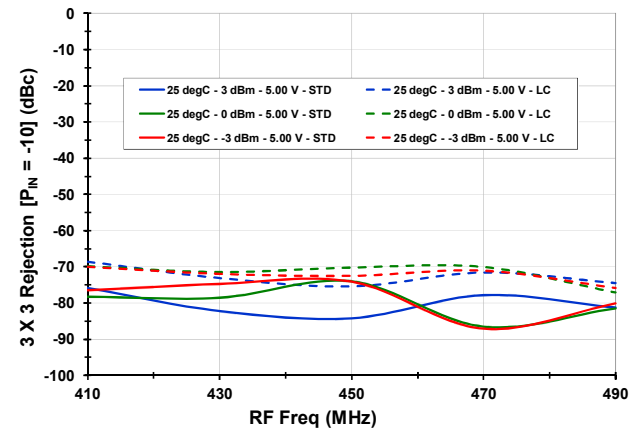
RF to IF Leakage vs. LO Level (130 MHz IF)



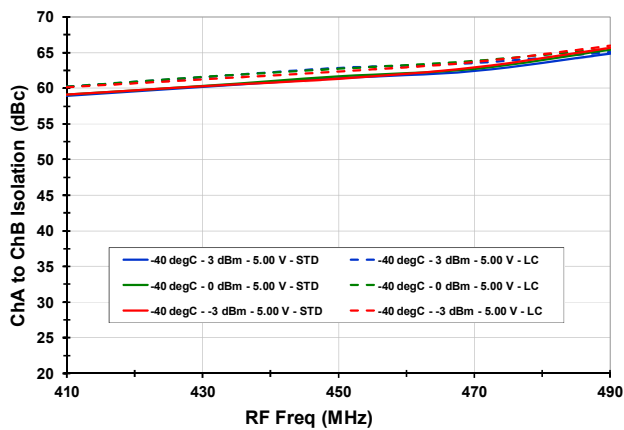
3RF x 3LO rejection vs. T_{CASE} (130 MHz IF)



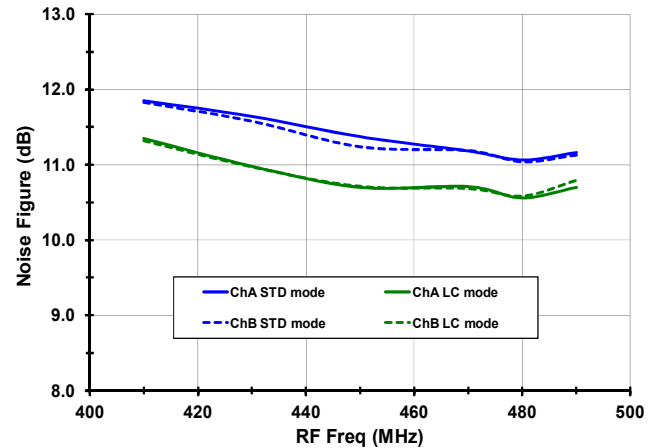
3RF x 3LO rejection vs. LO Level (130 MHz IF)

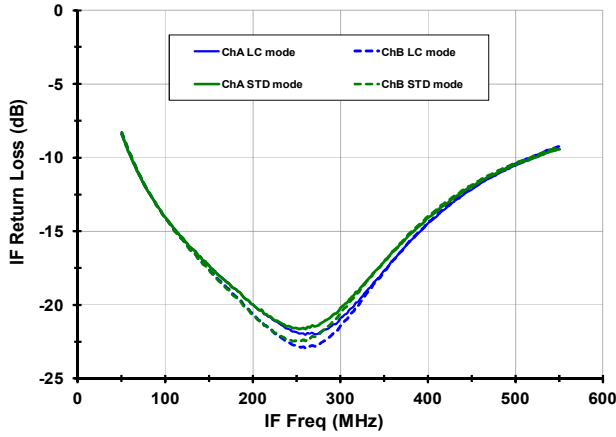
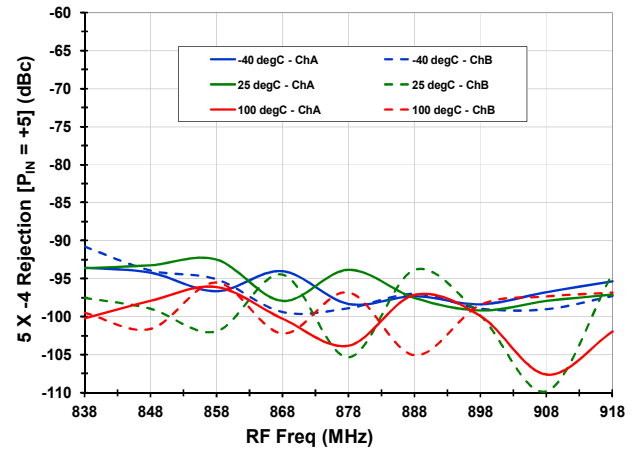
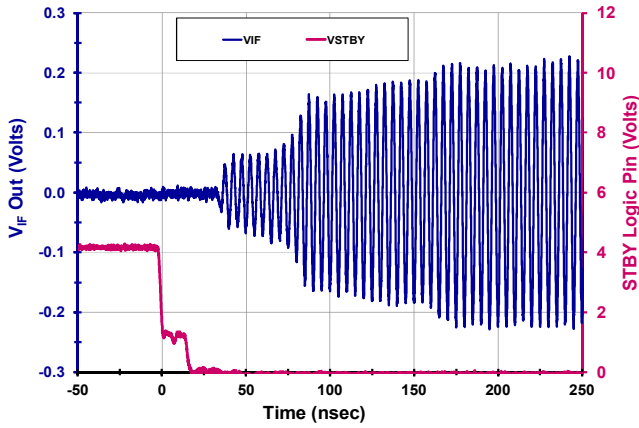
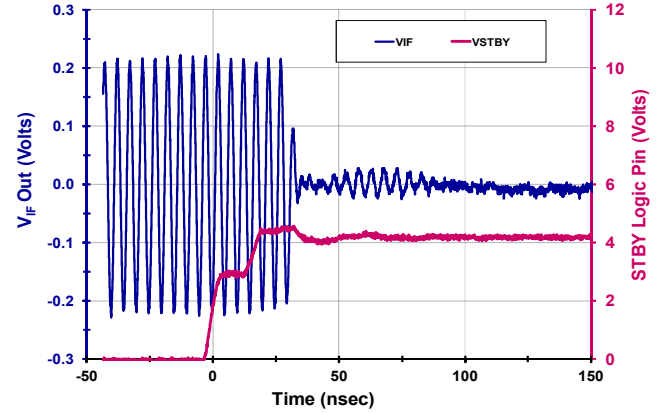
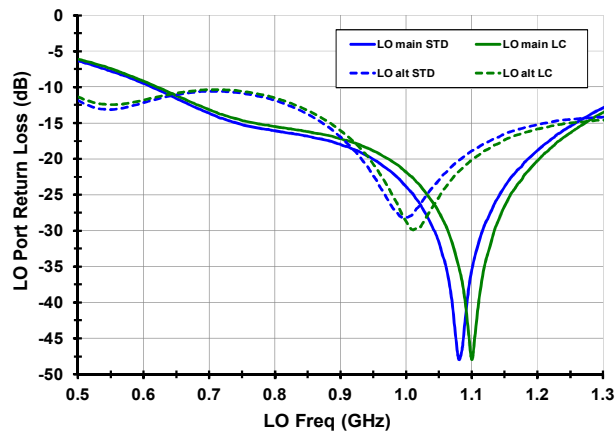
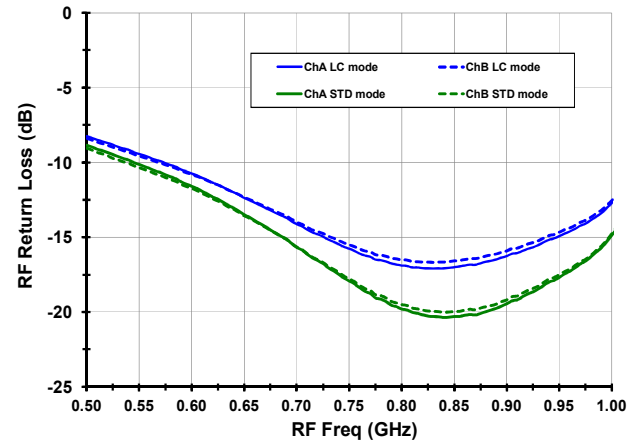


Channel Isolation vs. LO level (130 MHz IF)



Noise Figure (T_{CASE} = 25C)



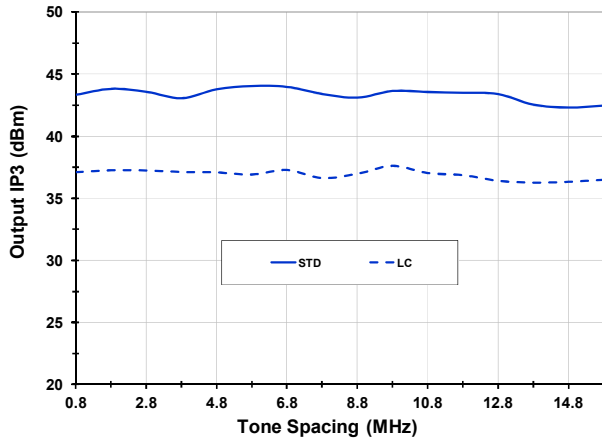
TYPICAL OPERATING CONDITIONS [General] (-13-)
EVkit IF Port Match ($T_A = 25C$)

SRF X -4LO Rejection (IF = 190M, STD Mode)

Settling Time (STBY -> V_{IL})

Settling Time (STBY -> V_{IH})

EVkit LO Port Match ($T_A = 25C, P_{MEAS} = 0$ dBm)

EVkit RF Port Match ($T_A = 25C$)


RF to IF Dual Downconverting Mixer

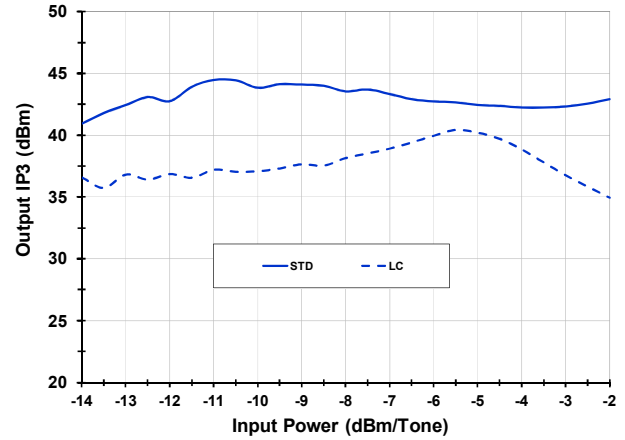
400 – 1000 MHz F1102NBGI

TYPICAL OPERATING CONDITIONS [General] (-14-)

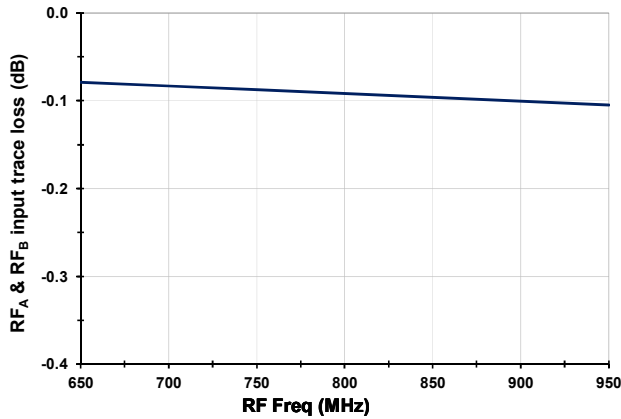
IP3_O vs. Δf (T_A = 25C, Freq = 850 MHz, IF = 200 MHz)



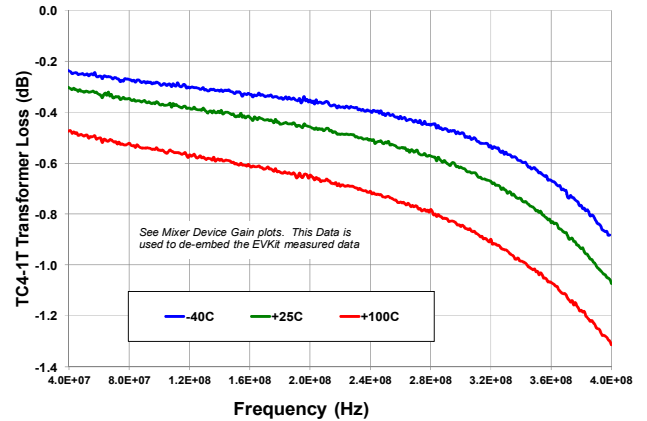
IP3_O vs. P_{IN} (T_A = 25C, Freq = 850 MHz, IF = 200 MHz)



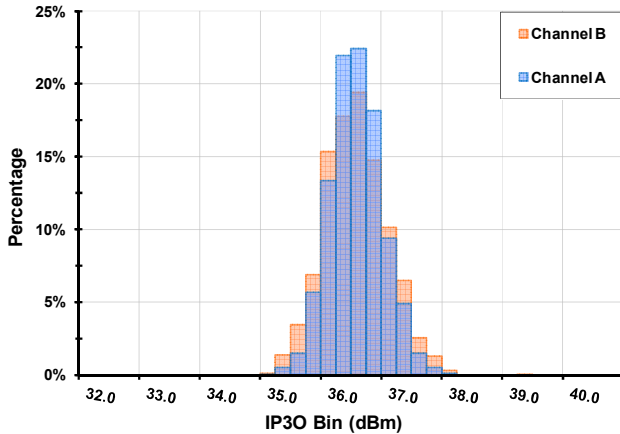
EVkit Input RF Trace Loss (T_A = 25C)



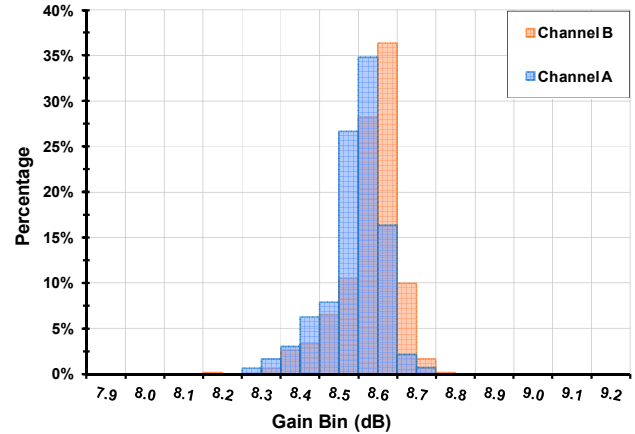
TC4-1T Transformer Loss



IP3_O Distribution (F_{RF} = 850 MHz, LC mode, N = 1598)



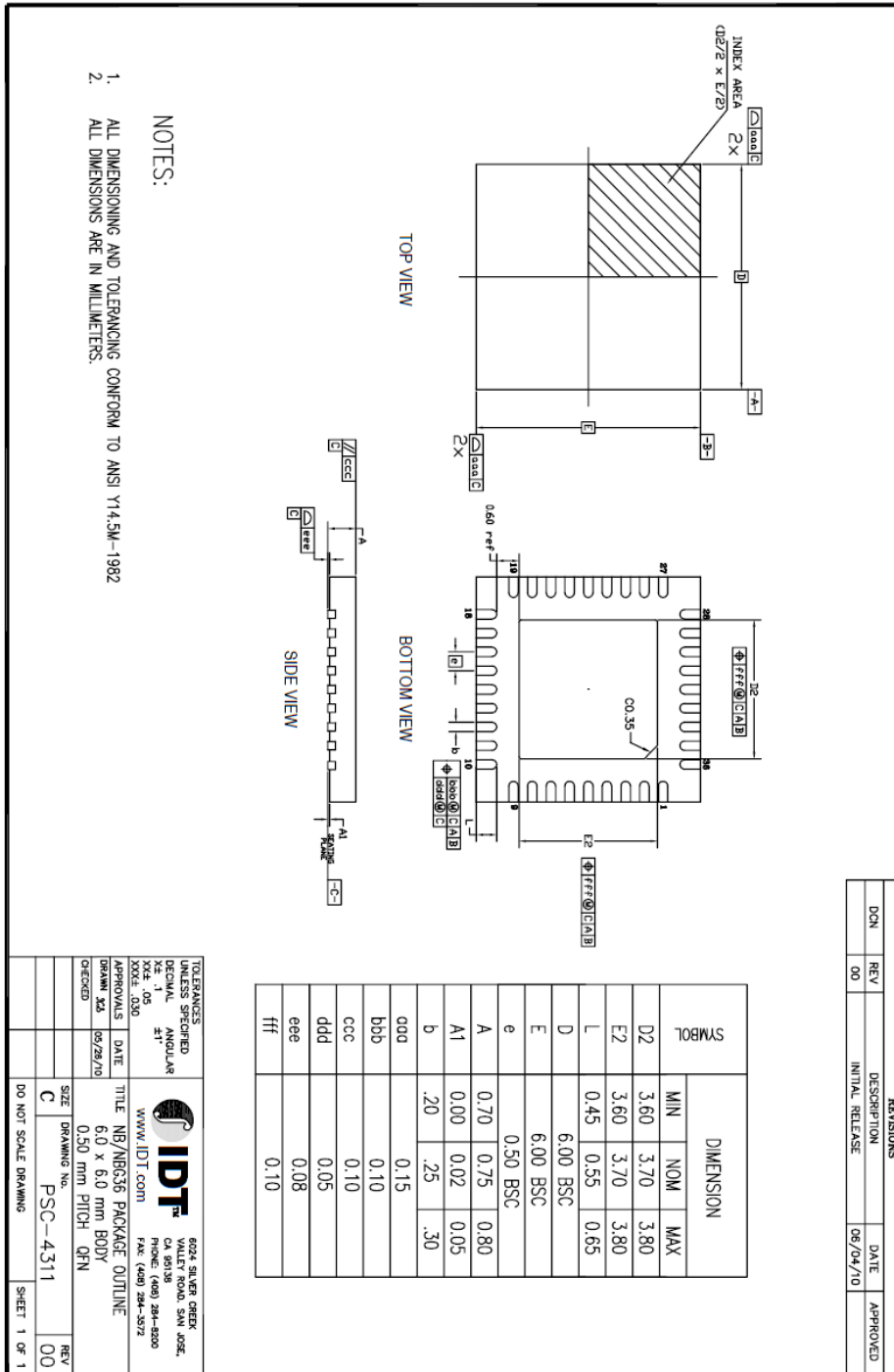
Gain Distribution (F_{RF} = 915 MHz, LC mode, N = 1598)



RF to IF Dual Downconverting Mixer

400 – 1000 MHz F1102NBGI

PACKAGE DRAWING (6X6 QFN)



REVISIONS			
DCH	REV	DESCRIPTION	DATE
	00	INITIAL RELEASE	06/04/10

TOLERANCES UNLESS SPECIFIED		6024 SILVER CREEK	
DECIMAL	ANGULAR	1500 SHERMAN AVE.	
XX.1	.1	CA 95138	
XX.10	.10	PHONE: (408) 284-8200	
XX.05	.05	WWW.IDT.COM	
XX.02	.02	FAX: (408) 284-3872	
APPROVALS		TITLE NB/NB636 PACKAGE OUTLINE	
DRW	326	DATE	09/28/10
CHECKED		SIZE	0.50 mm PITCH QFN
		DRAWING NO.	PSC-4311
		DO NOT SCALE DRAWING	
		REV	00
		SHEET	1 OF 1

PINOUTS

Black Text denotes recommended external connection

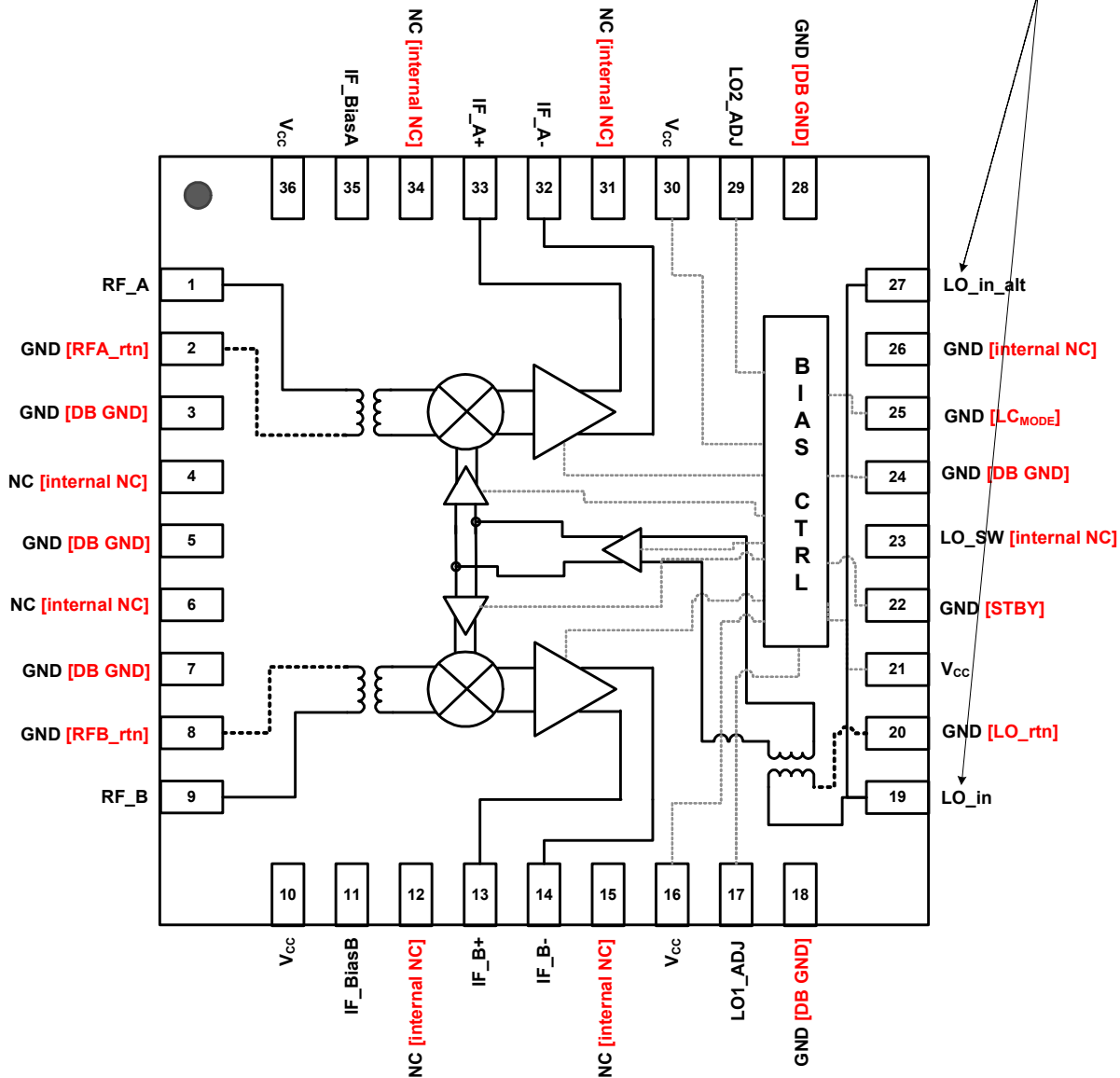
Red Text denotes internal Function or Connection

- DB GND = Downbonded to Paddle

- Internal NC = Pin not connected

Please Note!

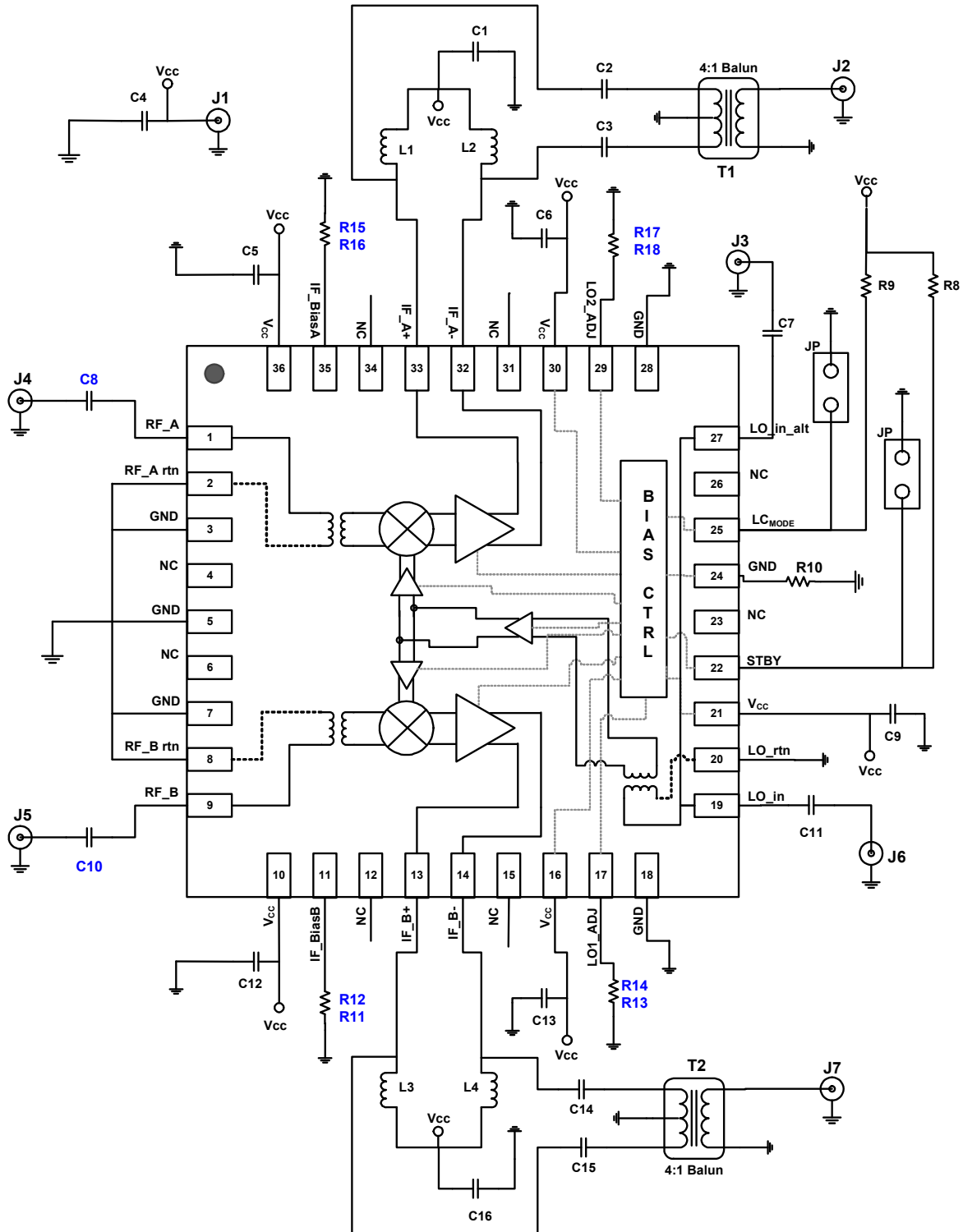
- Only connect to one LO feed
- Choose Either Pin 19 or Pin 27
- Do not connect the unused LO pin to ensure good LO return loss



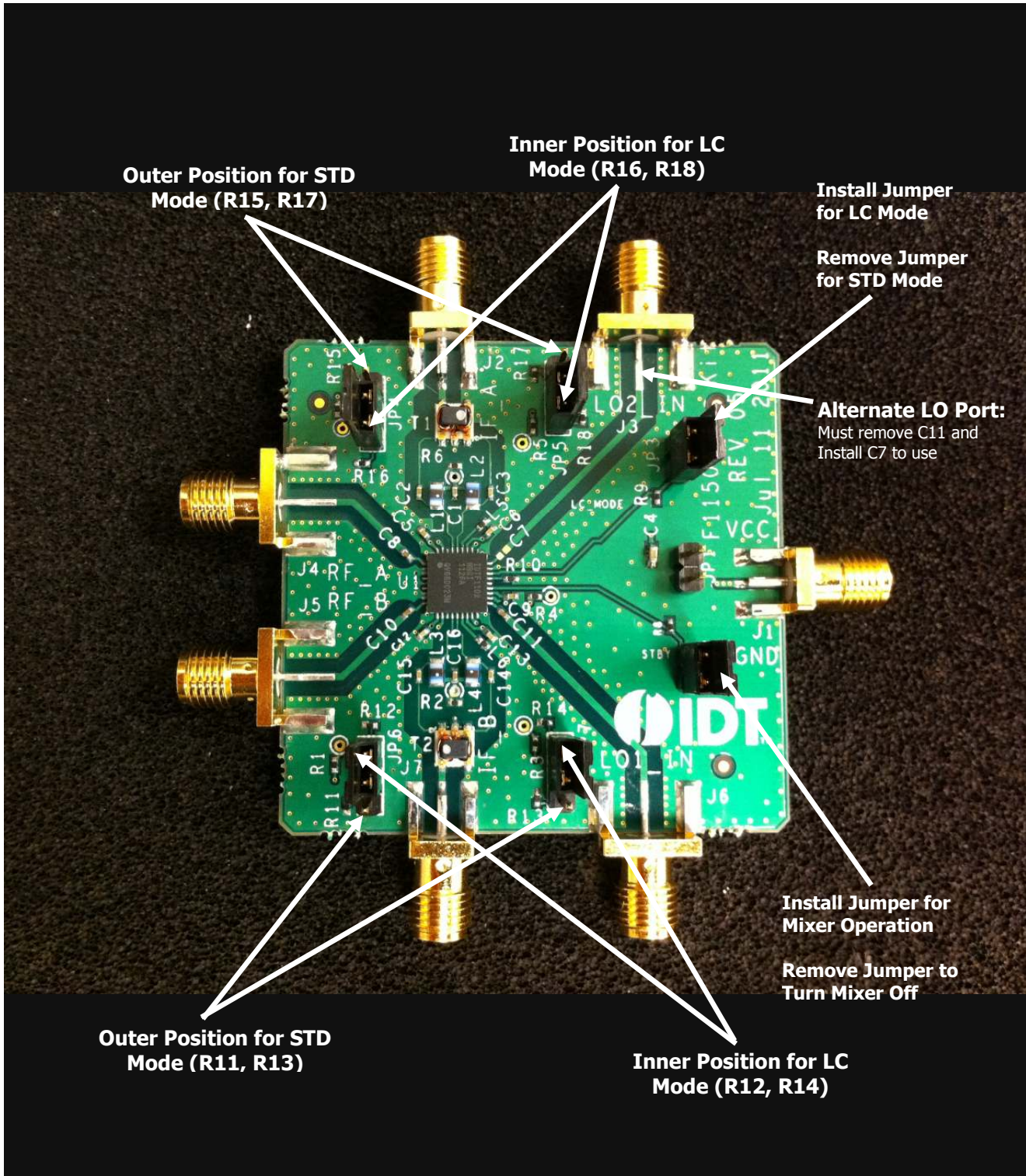
PIN DESCRIPTIONS

Pin	Name	Function
1	RF_A	Main Channel RF Input. Internally matched to 50Ω. DO NOT apply DC to these pins
2, 8, 20	RF_Artn, RF_Brtn, LO_rtn	Transformer Ground Returns. Ground these pins.
3, 5, 7, 18, 24, 28	GND	Ground these pins.
4, 6, 12, 15, 31, 23, 26, 34	N.C.	No Connection. Not internally connected. OK to connect to Vcc. OK to connect to GND
10, 16, 21, 30, 36	VCC	Power Supply. Bypass to GND with capacitors shown in the Typical Application Circuit as close as possible to pin.
9	RF_B	Diversity Channel RF Input. Internally matched to 50Ω
11	IF_BiasB	Connect the specified resistor from this pin to ground to set the bias for the Diversity IF amplifier. This is NOT a current set resistor
13, 14	IFB+, IFB-	Diversity Mixer Differential IF Output. Connect pullup inductors from each of these pins to VCC (see the Typical Application Circuit).
17	LO1_ADJ	Connect the specified resistor for either Standard or LC mode from this pin to ground to set the LO common buffer Icc
19, 27	LO_in LO_in_alt	Local Oscillator Input. Connect the LO to this port through the recommended coupling capacitor. Note that you can only drive one LO port at a time. Remove the series capacitor from the unused port.
25	LC_MODE	Low_Current Mode. Set this pin to low or ground for LC mode. Set to high or No-Connect for Standard mode. There is an internal pull-up resistor.
22	STBY	STBY Mode. Pull this pin high for Standby mode (~20 mA). Pull low or Ground for normal Operation
29	LO2_ADJ	Connect the specified resistor for either Standard or LC mode from this pin to ground to set the LO drive buffers Icc
32, 33	IFA-, IFA+	Main Mixer Differential IF Output. Connect pullup inductors from each of these pins to VCC (see the Typical Application Circuit).
35	IF_BiasA	Connect the specified resistor from this pin to ground to set the bias for the Main IF amplifier. This is NOT a current set resistor
	— EP	Exposed Pad. Internally connected to GND. Solder this exposed pad to a PCB pad that uses multiple ground vias to provide heat transfer out of the device into the PCB ground planes. These multiple via grounds are also required to achieve the noted RF performance.

EVKIT SCHEMATIC



EVKIT PICTURE/LAYOUT/OPERATION



EVKIT BOM
Default BOM:

For Standard Mode, Open the LC_{MODE} jumper in conjunction with positioning the 4 dual jumpers to select the resistors in **red**.

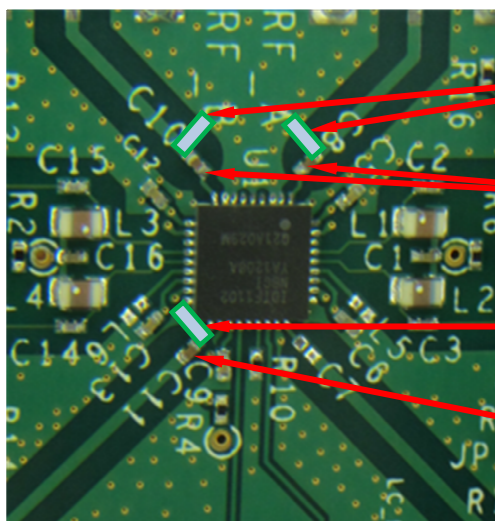
For Low Current Mode close the LC_{MODE} jumper in conjunction with positioning the 4 dual jumpers to select the resistors in **blue**.

F1102 BOM

Item #	Value	Size	Desc	Mfr. Part #	Mfr.	Part Reference	Qty
1	10nF	0402	CAP CER 1000PF 16V 10% X7R 0402	GRM155R71C103KA01D	MURATA	C1,5,6,9,12,13,16	7
2	1000pF	0402	CAP CER 1000PF 50V C0G 0402	GRM1555C1H102JA01D	MURATA	C2,3,14,15	4
3	150pF	0402	CAP CER 150PF 50V C0G 0402	GRM1555C1H151JA01D	MURATA	C8,10,11	3
4	9 pF	0402	Note: C7 and C11 cannot be installed together. C7 for Pin27 LO feed. C11 for Pin19 LO feed			C7	1
5	10uF	0603	CAP CER 10UF 6.3V X5R 0603	GRM188R60J106ME47D	MURATA	C4	1
6	Header 2 Pin	TH 2	CONN HEADER VERT SGL 2POS GOLD	961102-6404-AR	3M	JP1,2,3	3
7	Header 3 Pin	TH 3	CONN HEADER VERT SGL 3POS GOLD	961103-6404-AR	3M	JP4,5,6,7	4
8	SMA_END_LAUNCH	.062	SMA_END_LAUNCH (Small)	142-0711-821	Emerson Johnson	J1,2,7	3
9	SMA_END_LAUNCH	.062	SMA_END_LAUNCH (Big)	142-0701-851	Emerson Johnson	J3,4,5,6	4
10	270nH	0805	0805CS (2012) Ceramic Chip Inductor	0805CS-271XJLB	COILCRAFT	L1,2,3,4	4
11	27	0402	RES 27 OHM 1/10W 1% 0402 SMD	ERJ-2RKF27R0X	Panasonic	R11,15	2
12	62	0402	RES 62.0 OHM 1/10W 1% 0402 SMD	ERJ-2RKF62R0X	Panasonic	R12,16	2
13	91	0402	RES 91.0 OHM 1/10W 1% 0402 SMD	ERJ-2RKF91R0X	Panasonic	R13	1
14	180	0402	RES 180 OHM 1/10W 1% 0402 SMD	ERJ-2RKF1800X	Panasonic	R14	1
15	1.91K	0402	RES 1.91K OHM 1/10W 1% 0402 SMD	ERJ-2RKF1911X	Panasonic	R18	1
16	1.21K	0402	RES 1.21K OHM 1/10W 1% 0402 SMD	ERJ-2RKF1211X	Panasonic	R17	1
17	47K	0402	RES 47.0K OHM 1/16W 1% 0402 SMD	RC0402FR-0747K	Yageo	R8,9	2
18	0	0402	RES 0.0 OHM 1/10W 0402 SMD	ERJ-2GE0R00X	Panasonic	R1,2,3,4,5,6,7,10	8
19	4:1 Balun	SM-22	4:1 Center Tap Balun	TC4-1TG2+	Mini Circuits	T1,2	2
20	F1102	QFN-36	Diversity Downconverter (400 - 1000 MHz)	F1102NBGI	IDT	U1	1
21	PCB		EV Kit	F1102 EVkit Rev5			1

Modified BOM and EVKit (for 400 MHz bands):

EVkit Modifications for High Side Injection 400 MHz operation (see TOCs on pages 15 – 17)



Scrape resist from ground and add shunt 8 pF

Replace C8 and C10 with 18 pF

Scrape resist from ground and add shunt 1.8 pF

Replace C11 with 6.8 pF

TOPMARKINGS

